Advanced Battery Management PMIC with Inductive Boost LED and Three LDO Regulators

Data Sheet

ADP5350

FEATURES

- Switching mode USB battery charger
  - High accuracy and programmable charge terminal voltage and charge current
  - 3 MHz buck for high efficiency and small footprint
  - Tolerant input voltage from −0.5 V to +20 V (USB V_{VBUSx})
  - Power path control allows system to operate with dead or missing battery
  - Compliant with JEITA charge temperature specification
- Voltage-based state of charge (SOC) calculation algorithm
  - Extra low quiescent current in sleep mode
  - Battery impedance chemistry (Li-Ion) compensation
  - Battery temperature compensation
  - No need for external sense resistor
- Boost regulator with 5-channel LED driver
  - Support up to 4 LED in series or in parallel
  - 5 independent programmable LED current sinks
  - 64 programmable LED current levels (up to 20 mA)
  - Programmable on and off timer for LED blinking
  - Adaptive headroom control to maximize the efficiency
- Three 150 mA linear LDO regulators
  - Ultralow I_Q with zero load at 1 µA typical for LDO1
  - Optional load-switch full turn-on mode
- Full I²C programmability with dedicated interrupt pin

APPLICATIONS

- Rechargeable Li-Ion and Li-Ion polymer battery-powered devices
- Portable consumer devices
- Portable medical devices
- Portable instrumentation devices
- Wearable devices

GENERAL DESCRIPTION

The ADP5350, a power management IC (PMIC), combines one high performance buck regulator for single Li-Ion/Li-Ion polymer battery charging, a fuel gauge, a highly programmable boost regulator for LED backlight illumination, and three 150 mA LDO regulators.

The ADP5350 operates in trickle charge mode and in constant current (CC) and constant voltage (CV) fast charge mode. It features an internal field effect transistor (FET) that permits battery isolation on the system power side.

The ADP5350 fuel gauge is a space-saving and low current consuming solution. It is optimal for rechargeable Li-Ion battery-powered devices, and features a voltage-based, battery SOC measurement function.

TYPICAL APPLICATION CIRCUIT

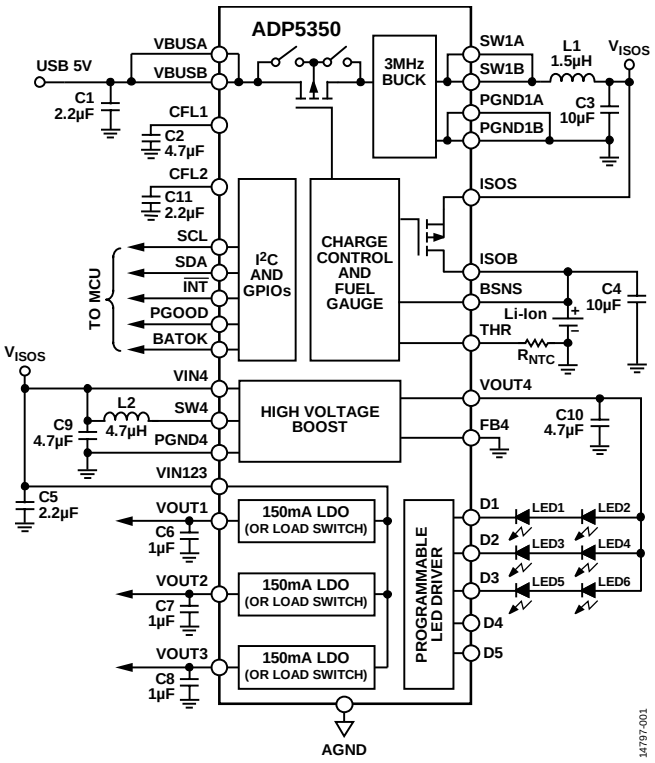

Figure 1.

The ADP5350 boost regulator operates at a 1.5 MHz switching frequency. It can be operated as a constant voltage regulator or as a supplemental constant current regulator for multiple LED backlight drivers.

The ADP5350 LED drivers can support a wide range of LED backlight configurations, either multiple LEDs in parallel or in series.

The ADP5350 low dropout (LDO) regulators are optimized to operate at low shutdown current and quiescent current to extend battery life. The device also operates as a load switch that can be fully turned off or on.

The I²C-compatible interface enables the programmability of all parameters, including status bit readback for operation monitoring and safety control.

The ADP5350 operates over the −40°C to +125°C junction temperature range and is available in a 32-lead, 5 mm × 5 mm LFCSP package and a 32-ball, 3 mm × 3 mm WLCSP package.

Rev. B Document Feedback

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One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700

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REVISION HISTORY

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2/2017—Revision 0: Initial Version

DETAILED FUNCTIONAL BLOCK DIAGRAM

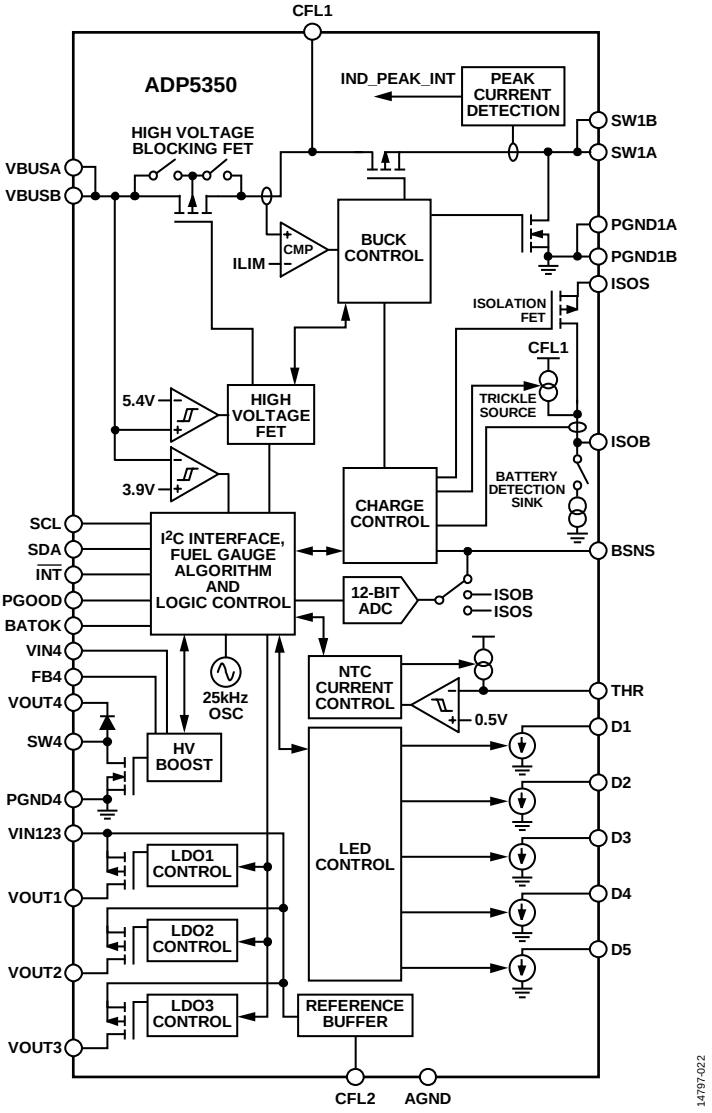


Figure 2. Detailed Functional Block Diagram

SPECIFICATIONS

BATTERY CHARGER SPECIFICATIONS

$-40°C < T_J < 125°C$, $V_{VBUSx} = 5.0$ V, $R_{NTC} = 47$ kΩ, $V_{VIN4} = V_{VIN123} = V_{ISOS} = 3.6$ V, C1 = 2.2 µF, C2 = 4.7 µF, C3 = 10 µF, C4 = 10 µF, C11 = 2.2 µF, L1 = 1.5 µH, all registers are at default values, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
GENERAL PARAMETERS		$T_J = 0°C$ to 85°C				
Undervoltage Lockout	V_{UVLO}	On BSNS, rising threshold, no V_{VBUSx}		2.45	2.6	V
		On BSNS, falling threshold, no V_{VBUSx}	2.2	2.3		V
Input Current Limit	I_{LIM}	Set ILIM[3:0] = 100 mA		92	100	mA
		Set ILIM[3:0] = 500 mA		475	500	mA
Operation Current	I_Q	All enabled, no load, from VBUSx pin		4	6	mA
		Only fuel gauge enabled (active), from ISOB, no V_{VBUSx}		160	230	µA
		Only fuel gauge enabled (sleep), from ISOB, no V_{VBUSx}[1]		4		µA
		Only boost regulator enabled, all LEDs enabled, no LED current, from ISOB, no V_{VBUS}		2	2.6	mA
		Only LDO1 enabled, from ISOB, no V_{VBUSx}		0.8	4	µA
		Only LDO2 enabled, from ISOB, no V_{VBUSx}		160	230	µA
		Only LDO3 enabled, from ISOB, no V_{VBUSx}		160	230	µA
Shutdown Current	I_{STDN}	All disabled, from ISOB and BSNS, no V_{VBUSx}		0.2	2.8	µA
CHARGING PARAMETERS						
Fast Charge Current, Constant Current Mode	I_{CHG}	Programmable via I²C, battery voltage > V_{TRK_DEAD}	25		650	mA
Fast Charge Current Accuracy		$I_{CHG} = 200$ mA	180	200	220	mA
		$T_J = 25°C$, $I_{CHG} = 200$ mA	−2.5		+2.5	%
Trickle Charge Current[2]	I_{TRK_DEAD}		16	20	25	mA
Weak Charge Current	I_{CHG_WEAK}	When $V_{TRK_DEAD} < V_{BSNS} < V_{WEAK}$		$I_{CHG} + I_{TRK_DEAD}$		mA
Dead Battery, Trickle to Weak Charge Threshold[2]	V_{TRK_DEAD}	On BSNS	2.4	2.5	2.62	V
Weak Battery						
Weak to Fast Charge Threshold[2]	V_{WEAK}	On BSNS	2.9	3.0	3.15	V
Weak Battery Threshold Hysteresis[1]	ΔV_{WEAK}			90		mV
Battery Termination Voltage[2]	V_{TRM}	On BSNS, $T_J = 0°C$ to 85°C	4.158	4.200	4.242	V
		On BSNS, $T_J = 25°C$	−0.3		+0.3	%
Battery Overvoltage Threshold	V_{BAT_OV}	Relative to CFL1 voltage, BSNS rising, $V_{CLF1} = 4.0$ V	$V_{CFL1} - 0.15$			V
Charge Complete Current[2]	I_{END}	$V_{BSNS} = V_{TRM}$, $T_J = 0°C$ to 85°C	20	35	50	mA
Recharge Voltage Differential[2]	V_{RCH}	Relative to V_{TRM}, BSNS falling		260		mV
Battery Node Short Threshold Voltage[2]	V_{BAT_SHR}		2.3	2.4	2.52	V
CHARGER DC-TO-DC REGULATOR						
Switching Frequency	f_{SW_CHG}		2.7	3	3.3	MHz
Maximum Duty Cycle[3]	D_{MAX}			96		%
Peak Inductor Current	I_{L1_PK}		1500	1750	2200	mA
Regulated System Voltage	V_{ISOS_TRK}	$V_{BSNS} < V_{TRK_DEAD}$, trickle charge mode		$V_{TRM} + 0.1$		V

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
DC to DC Power						
PMOS On Resistance	R_{DSON_P}			220	280	mΩ
NMOS On Resistance	R_{DSON_N}			160	210	mΩ
SW1x Pin Leakage Current	I_{SW1x}	V_{SW1x} = 5.0 V			2	µA
BATTERY ISOLATION FIELD EFFECT TRANSISTOR (FET)						
LFCSP Package				202	300	mΩ
WLCSP Package				125	170	mΩ
	V_{ISOS_FC}	$V_{TRK_DEAD} < V_{BSNS}$, fast charging constant current mode	3.15	3.3	3.45	V
Battery Supplementary Threshold	V_{TH_ISO}	$V_{ISOS} < V_{ISOB}$	0	5	14	mV
HIGH VOLTAGE BLOCKING FET						
VBUSx Input						
High Voltage Blocking FET On Resistance	R_{DSON_HV}	I_{VBUS} = 100 mA, T_J = 0°C to 85°C		330		mΩ
Current, Suspend Mode	$I_{SUSPEND}$	EN_DCDC = low		1.45	1.8	mA
Input Voltage						
Power-Good Threshold	V_{VBUSOK}					
Rising	V_{VBUSOK_RISE}		3.77	3.9	4.03	V
Falling	V_{VBUSOK_FALL}		3.47	3.6	3.73	V
Overvoltage Threshold	V_{VBUS_OV}		5.38	5.45	5.53	V
Overvoltage Threshold Hysteresis				75		mV
THERMAL CONTROL						
Thermal Early Warning Temperature[1]	T_{SD_W}			130		°C
Thermal Shutdown Temperature[1]	T_{SD}	T_J rising		140		°C
		T_J falling		110		°C
THERMISTOR CONTROL						
Resistance Thresholds by Battery Temperature[4]		R_{NTC} = 47 kΩ, BETA_NTC = 3800, T_J = 0°C to +85°C				
LFCSP Package						
Cool to Cold	R_{COOL_COLD}		131	151.2	175	kΩ
Cold to Cool	R_{COLD_COOL}		126	145.6	168	kΩ
Typical to Cool[4]	R_{TYP_COOL}		75	86.5	99	kΩ
Cool to Typical[4]	R_{COOL_TPY}		72.5	83.1	95	kΩ
Warm to Typical[4]	R_{WARM_TYP}		20	23.7	27	kΩ
Typical to Warm[4]	R_{TYP_WARM}		19.3	22	24.6	kΩ
Hot to Warm	R_{HOT_WARM}		12	13.9	16	kΩ
Warm to Hot	R_{WARM_HOT}		11	12.7	14.4	kΩ
WLCSP Package						
Cool to Cold	R_{COOL_COLD}		140	162	185	kΩ
Cold to Cool	R_{COLD_COOL}		133	156	180	kΩ
Typical to Cool[4]	R_{TYP_COOL}		77	90	102	kΩ
Cool to Typical[4]	R_{COOL_TPY}		75	86	100	kΩ
Warm to Typical[4]	R_{WARM_TYP}		20	23	26	kΩ
Typical to Warm[4]	R_{TYP_WARM}		18.5	21	24	kΩ
Hot to Warm	R_{HOT_WARM}		11.5	13	15	kΩ
Warm to Hot	R_{WARM_HOT}		10.5	12	13.5	kΩ

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
BATTERY DETECTION						
Sink Current	I_{SINK}		15	25	35	mA
Source Current	I_{SOURCE}		7	10	13	mA
Battery Threshold						
Low	V_{BATL}		1.8	1.9	2.0	V
High	V_{BATH}		3.3	3.4	3.55	V
Battery Detection Timer	t_{BATOK}			333		ms
TIMERS						
Start Charging Delay Timer	t_{START}			1		sec
Trickle Charge Timer[2]	t_{TRK}			60		min
Fast Charge Timer[2]	t_{CHG}			600		min
Charge Complete Timer	t_{END}	$V_{BSNS} = V_{TRM}$, $I_{CHG} < I_{END}$		7.5		min
Deglitch Timer	t_{DG}	Applies to V_{TRM}, V_{RCH}, I_{END}, V_{WEAK}, V_{TRK_DEAD}, V_{VBUSOK_FALL}, and V_{VBUSOK_RISE}		31		ms
Watchdog Timer[2]	t_{WD}			32		sec
Safety Timer	t_{SAFE}			40		min
Battery Node Short Timer[2]	t_{BAT_SHR}			30		sec
I²C (SCL AND SDA)						
Input Voltage						
Low Level	V_{IL}	Applies to SCL, SDA			0.5	V
High Level	V_{IH}	Applies to SCL, SDA	1.2			V
Low Level Output Voltage	V_{OL}	Applies to SDA, I_{SDA_SINK} = 2 mA			0.4	V
PGOOD AND BATOK						
PGOOD Pin						
Leakage Current	I_{PGOOD_LEAK}	V_{PGOOD} = 5 V			0.5	µA
Output Low Voltage	V_{PGOOD_LOW}	I_{PGOOD} = 1 mA		50	100	mV
BATOK Pin						
Leakage Current	I_{BATOK_LEAK}	V_{BATOK} = 5 V			0.5	µA
Output Low Voltage	V_{BATOK_LOW}	I_{BATOK} = 1 mA		50	100	mV

[1] Specification is not production tested, but is supported by characterization data at initial product release.
[2] These values are programmable via the I²C interface. Values are given with default register values.
[3] Guaranteed by design.
[4] Typical temperature is the normal operation temperature.

BATTERY FUEL GAUGE SPECIFICATIONS

$V_{VIN4} = V_{VIN123} = V_{ISOS}$ = 4.2 V, T_J = −40°C to +125°C for minimum/maximum specifications, and T_A = 25°C for typical specifications, unless otherwise noted

Table 2.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
BATTERY VOLTAGE MONITORING					
Battery Monitor Voltage					
Range		2.7		4.5	V
Resolution	Based on 12-bit ADC		1.09		mV
Voltage Reading Accuracy	T_J = 25°C	−12.5		+12.5	mV
	T_J = 0°C to +85°C	−30		+30	mV

BOOST AND LED DRIVER SPECIFICATIONS

V_{VIN4} = V_{VIN123} = V_{ISOS}= 3.6 V, C9 = 4.7 µF, C10 = 4.7 µF, L2 = 4.7 µH, T_J = −40°C to +125°C for minimum/maximum specifications, and T_A = 25°C for typical specifications, unless otherwise noted.

Table 3.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Input Voltage Range	V_{VIN4}		2.85		5.5	V
UNDERVOLTAGE LOCKOUT	$V_{UVLO_VIN4_RISE}$	VIN4 rising		2.7	2.85	V
	$V_{UVLO_VIN4_FALL}$	VIN4 falling	2.5	2.6		V
OUTPUT CHARACTERISTICS		Standalone operation mode				
Output Voltage Range	V_{VOUT4}		V_{ISOS}		16	V
FB4 Voltage Reference	V_{FB4}		0.62	0.65	0.68	V
		T_J = 25°C	−1.5		+1.5	%
Line Regulation[1]	$\Delta V_{VOUT4}/V_{VIN4}$			0.1		%/V
POWER GOOD (PGOOD)		Standalone operation mode				
PGOOD Rising Threshold	V_{PGOOD4_RISE}			90		%
PGOOD Hysteresis	V_{PGOOD4_HYS}			5.5		%
PGOOD Falling Delay	t_{PGOOD4_FALL}			2		ms
PGOOD Rising Delay	t_{PGOO4_RISE}			2		ms
SW4 CHARACTERISTICS						
SW4 On Resistance	R_{DSON_NFET}	NFET at V_{VIN4} = 3.6 V		460	800	mΩ
Overvoltage Threshold	V_{OVP4}	Boost OVP threshold = 18.5 V	17.5	18.5	19.5	V
		Boost OVP threshold = 15 V	14.2	15	15.8	V
		Boost OVP threshold = 10 V	9.5	10	10.5	V
		Boost OVP threshold = 5.6 V	5.32	5.6	5.9	V
	V_{OVP4_HYS}	OVP recovery hysteresis[1]		5		%
Start-Up Time	t_{SS4}			1.0	2.7	ms
CURRENT LIMIT	I_{LIM4}	BST_IPK = 0	510	600	690	mA
		BST_IPK = 1		300		mA
OSCILLATOR CIRCUIT						
Switching Frequency	f_{SW4}		1.35	1.5	1.65	MHz
Minimum On Time	t_{MIN_ON4}			50		ns
LED CURRENT CONTROL						
LED Current						
Range, 6-Bit	I_{Dx}		0		20	mA
Accuracy		I_{Dx} = 20 mA	−10		+10	%
Matching		I_{Dx} = 20 mA		2.0		%
LED Pin Leakage Current	I_{Dx_LEAK}				0.5	µA
LED Current Ramp-Up Time	t_{Dx_RISE}	I_{Dx} = 20 mA		20		µs
LED Current Ramp-Down Time	t_{Dx_FALL}	I_{Dx} = 20 mA		20		µs
LED Source Headroom	V_{Dx_HDRM}	ILEDx[5:0] =11111		0.65	0.75	V
LED ON/OFF TIMER						
LED Timer Accuracy		Including on timer and off timer	−10		+10	%

[1] Specification is not production tested, but is supported by characterization data at initial product release.

LDO SPECIFICATIONS

V_{VBUSx} = 5.0 V, V_{VIN4} = V_{VIN123} = V_{ISOS}= 3.6 V, C5 = C6 = C7 = C8 = 1 µF; T_J = −40°C to +125°C for minimum/maximum specifications, and T_A = 25°C for typical specifications, unless otherwise noted.

Table 4.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
LDO1 INPUT VOLTAGE RANGE	V_{VIN123}		2.56		5.5	V
KEEPALIVE LDO1						
UNDERVOLTAGE LOCKOUT	$V_{UVLO_LDO1_RISE}$	VIN123 rising			2.56	V
	$V_{UVLO_LDO1_FALL}$	VIN123 falling	1.78			V
	$V_{UVLO_LDO1_HYS}$			200		mV
Output Voltage Range	V_{VOUT1}	Fuse trim or I²C, four bits	1.0		4.2	V
Output Accuracy		I_{OUT1} = 10 mA, T_J = 25°C	−1		+1	%
		I_{OUT1} = 10 mA	−2.0		+2.0	%
Line Regulation	$\Delta V_{VOUT1}/V_{IN123}$	V_{VIN123} = (V_{VOUT1} + 0.5 V) to 5.5 V	−0.1		+0.1	%/V
Load Regulation	$\Delta V_{VOUT1}/I_{OUT1}$	I_{OUT1} = 100 µA to 150 mA			0.015	%/mA
Dropout Voltage	V_{DROP_OUT1}	V_{VOUT1} = 3.3 V, I_{OUT1} = 10 mA		54	130	mV
		V_{VOUT1} = 3.3 V, I_{OUT1} = 150 mA		150	240	mV
Current-Limit Threshold	I_{LIM_LDO1}		200	300	440	mA
Output Noise[1]	V_{NOISE_LDO1}	10 Hz to 100 kHz, V_{VIN123}= 3.6 V, V_{VOUT1} = 3.3 V		100		µV rms
Power Supply Rejection Ratio[1]	PSRR	100 Hz, V_{VIN123}= 3.6 V, V_{VOUT1} = 3.3 V, I_{OUT1} = 10 mA		40		dB
		1 kHz, V_{VIN123}= 3.6 V, V_{VOUT1} = 3.3 V, I_{OUT1} = 10 mA		35		dB
LDO Start-Up Time	t_{SS_LDO1}	V_{VOUT1} = 3.3 V, LDO mode		600		µs
PGOOD Rising Threshold	V_{PGOOD1_RISE}	Only effective in LDO mode		90		%
PGOOD Hysteresis	V_{PGOOD1_HYS}			4.5		%
PGOOD Falling Delay	t_{PGOOD1_Fall}			120		µs
PGOOD Rising Delay	t_{PGOOD1_RISE}			2		ms
Load Switch Turn-On Rise Time	$t_{RISE_SWITCH1}$	V_{OUT1} = 3.3 V, load switch mode		120		µs
Load Switch On Resistance	$R_{DSON_SWITCH1}$			700		mΩ
C_{OUT} Discharge Switch On Resistance	R_{DIS_LDO1}	V_{VIN123} = 3.6 V		500		Ω
LDO2 INPUT VOLTAGE RANGE	V_{VIN4}	V_{VIN4} = V_{VIN123}	2.85		5.5	V
GENERAL-PURPOSE LDO2						
Undervoltage Lockout	$V_{UVLO_LDO2_RISE}$	VIN4 rising		2.7	2.85	V
	$V_{UVLO_LDO2_FALL}$	VIN4 falling	2.5	2.6		V
	$V_{UVLO_LDO2_HYS}$			100		mV
Output Voltage Range	V_{VOUT2}	Fuse trim or I²C, 4 bits	1.0		4.2	V
Output Accuracy		I_{OUT2} = 10 mA, T_J = 25°C	−0.75		+0.75	%
		I_{OUT2} = 10 mA	−1.5		+1.5	%
Line Regulation	$(\Delta V_{VOUT2})/V_{VIN123}$	V_{VIN123} = (V_{VOUT2} + 0.5 V) to 5.5 V	−0.1		+0.1	%/V
Load Regulation	$(\Delta V_{VOUT2})/I_{OUT2}$	I_{OUT2} = 100 µA to 150 mA			0.01	%/mA
Dropout Voltage						
LFCSP Package	V_{DROP_OUT2}	V_{VOUT2} = 3.3 V, I_{OUT2} = 10 mA		76	140	mV
WFCSP Package	V_{DROP_OUT2}	V_{VOUT2} = 3.3 V, I_{OUT2} = 10 mA		65	120	mV
LFCSP Package	V_{DROP_OUT2}	V_{VOUT2} = 3.3 V, I_{OUT2} = 150 mA		100	180	mV
WFCSP Package	V_{DROP_OUT2}	V_{VOUT2} = 3.3 V, I_{OUT2} = 150 mA		80	150	mV
Current-Limit Threshold	I_{LIM_LDO2}		220	320	430	mA

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
Output Noise[1]	V_{NOISE_LDO2}	10 Hz to 100 kHz, V_{VIN123} = 3.6 V, V_{VOUT2} = 3.3 V		120		µV rms
Power Supply Rejection Ratio[1]	PSRR	100 Hz, V_{IN123} = 3.6 V, V_{VOUT2} = 3.3V, I_{OUT2} = 10 mA		60		dB
		1 kHz, V_{IN123} = 3.6 V, V_{VOUT2} = 3.3 V, I_{OUT2} = 10 mA		50		dB
LDO Start-Up Time	t_{SS_LDO2}	V_{VOUT2} = 3.3 V, LDO mode		80		µs
Load Switch Turn-On Rise Time	$t_{RISE_SWITCH2}$	V_{VOUT2} = 3.3 V, load switch mode		80		µs
Load Switch On Resistance						
LFCSP Package	$R_{DSON_SWITCH2}$			400	600	mΩ
WFCSP Package	$R_{DSON_SWITCH2}$			300	500	mΩ
C_{OUT} Discharge Switch On Resistance	R_{DIS_LDO2}	V_{VIN123} = 3.6 V		500		Ω
LDO3 INPUT VOLTAGE RANGE	V_{VIN4}	V_{VIN4} = V_{VIN123}	2.85		5.5	V
GENERAL-PURPOSE LDO3						
UNDERVOLTAGE LOCKOUT	$V_{UVLO_LDO3_RISE}$	VIN4 rising		2.7	2.85	V
	$V_{UVLO_LDO3_FALL}$	VIN4 falling	2.5	2.6		V
	$V_{UVLO_LDO3_HYS}$			100		mV
Output Voltage Range	V_{VOUT3}	Fuse trim or I^2C, four bits	1.0		4.2	V
Output Accuracy	V_{VOUT3}	I_{OUT3} = 10 mA, T_J = +25°C	−0.75		+0.75	%
		I_{OUT3} = 10 mA	−1.5		+1.5	%
Line Regulation	$\Delta V_{OUT3}/V_{VIN123}$	V_{VIN123} = (V_{VOUT3} + 0.5 V) to 5.5 V	−0.1		+0.1	%/V
Load Regulation	$\Delta V_{OUT3}/I_{OUT3}$	I_{OUT3} = 100 µA to 150 mA			0.01	%/mA
Dropout Voltage						
LFCSP Package	V_{DROP_OUT3}	V_{VOUT3} = 3.3 V, I_{OUT3} = 10 mA		76	140	mV
WFCSP Package	V_{DROP_OUT3}	V_{VOUT3} = 3.3 V, I_{OUT3} = 10 mA		65	120	mV
LFCSP Package	V_{DROP_OUT3}	V_{VOUT3} = 3.3 V, I_{OUT3} = 150 mA		100	180	mV
WFCSP Package	V_{DROP_OUT3}	V_{VOUT3} = 3.3 V, I_{OUT3} = 150 mA		80	150	mV
Current Limit Threshold	I_{LIM_LDO3}		220	320	430	mA
Output Noise[1]	V_{NOISE_LDO3}	10 Hz to 100 kHz, V_{VIN123} = 3.6 V, V_{VOUT3} = 3.3 V		120		µV rms
Power Supply Rejection Ratio[1]	PSRR	100 Hz, V_{VIN123} = 3.6 V, V_{VOUT3} = 3.3 V, I_{OUT3} = 10 mA		60		dB
		1 kHz, V_{VIN123} = 3.6 V, V_{VOUT3} = 3.3 V, I_{OUT3} = 10 mA		50		dB
LDO Start-Up Time	t_{SS_LDO3}	V_{VOUT3} = 3.3 V, LDO mode		80		µs
Load Switch Turn-On Rise Time	$t_{RISE_SWITCH3}$	V_{VOUT3} = 3.3 V, load switch mode		80		µs
Load Switch On Resistance						
LFCSP Package	$R_{DSON_SWITCH3}$			400	600	mΩ
WFCSP Package	$R_{DSON_SWITCH3}$			300	500	mΩ
C_{OUT} Discharge Switch On Resistance	R_{DIS_LDO3}	V_{IN123} = 3.6 V		500		Ω

[1] Guaranteed by design.

RECOMMENDED INPUT AND OUTPUT CAPACITANCE AND INDUCTANCE SPECIFICATIONS

Table 5.

Parameter	Min	Typ	Max	Unit
EFFECTIVE CAPACITANCE				
Charger Capacitance				
VBUSx Pin	1.0	2.2		µF
CFL1 Pin	2.0	4.7		µF
CFL2 Pin	1.0	2.2		µF
ISOS Pin	4.0	10		µF
ISOB Pin	4.0	10		µF
LDO Capacitance				
VIN123 Pin	0.7	1		µF
LDO1	0.7	1		µF
LDO2	0.7	1		µF
LDO3	0.7	1		µF
Boost Capacitance				
VIN4 Pin	1	4.7		µF
VOUT4 Pin	0.47	4.7		µF
INDUCTANCE				
Buck	0.5	1.5	2.2	µH
Boost	2	4.7	10	µH

I²C-COMPATIBLE INTERFACE TIMING SPECIFICATIONS

Table 6.

Parameter	Symbol	Min	Typ	Max	Unit
I²C-COMPATIBLE INTERFACE					
Capacitive Load, Each Bus Line	C_S			400	pF
SCL					
Clock Frequency	f_{SCL}			400	kHz
High Time	t_{HIGH}	0.6			µs
Low Time	t_{LOW}	1.3			µs
Data					
Setup Time	$t_{SU,DAT}$	100			ns
Hold Time[1]	$t_{HD,DAT}$	0		0.9	µs
Setup Time for Repeated Start	$t_{SU,STA}$	0.6			µs
Hold Time for Start/Repeated Start	$t_{HD,STA}$	0.6			µs
Bus Free Time Between a Stop and a Start Condition	t_{BUF}	1.3			µs
Setup Time for Stop Condition	$t_{SU,STO}$	0.6			µs
SCL/SDA					
Rise Time	t_R			300	ns
Fall Time	t_F			300	ns
Pulse Width of Suppressed Spike	t_{SP}	0		50	ns

[1] A master device must provide a hold time of at least 300 ns for the SDA signal to bridge the undefined region of the falling edge of SCL. See Figure 3, the I²C timing diagram.

Timing Diagram

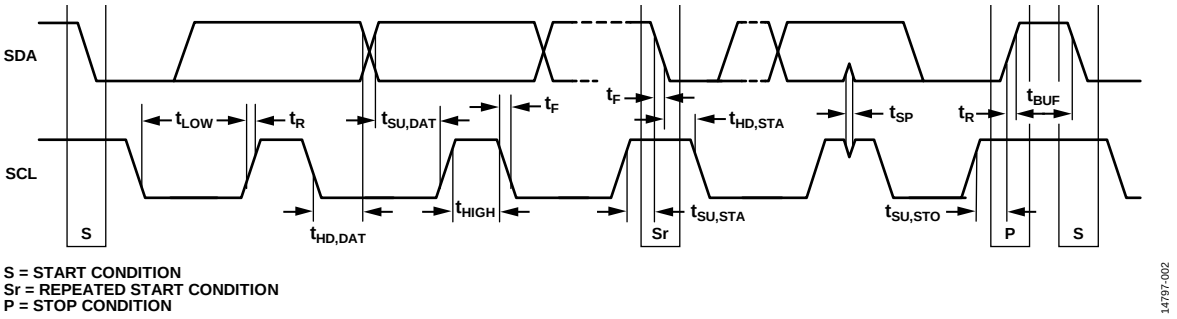


Figure 3. I²C Timing Diagram

ABSOLUTE MAXIMUM RATINGS

Table 7.

Parameter	Rating
VBUSA, VBUSB to PGND1	−0.5 V to +20 V
SW4, VOUT4, D1, D2, D3, D4, D5 to PGND4	−0.5 V to +20 V
FB4	−0.3 V to +6 V
CFL2 to AGND	−0.3 V to +3.3 V
PGND1, PGND4 to AGND	−0.3 V to +0.3 V
All Other Pins to AGND	−0.3 V to +6 V
Continuous Drain Current, Battery Supplementary Mode, from ISOB to ISOS, T_J = 125°C	1.1 A
Storage Temperature Range	−65°C to +150°C
Operating Junction Temperature Range	−40°C to +125°C
Soldering Conditions	JEDEC J-STD-020

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment.

Careful attention to PCB thermal design is required. θ_{JA} is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure. θ_{JC} is the junction to case thermal resistance.

Table 8. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
CP-32-12[1]	42	2.1	°C/W
CB-32-1	64	0.7	°C/W

[1] Thermal impedance simulated values are based on a JEDEC 2S2P thermal test board with nine thermal vias. See JEDEC JESD51.

Maximum Power Dissipation

The maximum safe power dissipation in the ADP5350 package is limited by the associated rise in junction temperature (T_J) on the die. At approximately 150°C, which is the glass transition temperature, the plastic changes its properties. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the ADP5350. Exceeding a junction temperature of 175°C for an extended period of time can result in changes in the silicon devices that potentially cause failure.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

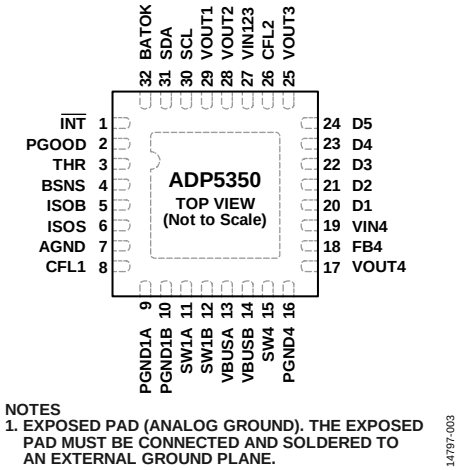


Figure 4. LFCSP Pin Configuration (Top View)

Table 9. LFCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
1	$\overline{\text{INT}}$	Processor Interrupt (Active Low). This pin requires an external pull-up resistor. If this pin is not used, it can be left floating.
2	PGOOD	Power-Good Signal Output. This open-drain output is the power-good signal for the selected channels.
3	THR	Battery Pack Thermistor Connection.
4	BSNS	Battery Voltage Sense Pin.
5	ISOB	Battery Supply Side Input to Internal Isolation FET/Battery Current Regulation FET.
6	ISOS	Charger Supply Side Input to Internal Isolation FET/Battery Current Regulation FET.
7	AGND	Analog Ground.
8	CFL1	Power input to the charger regulator. Connect a ceramic filter capacitor between this pin and either PGND1A or PGND1B.
9, 10	PGND1A, PGND1B	Power Ground for the Battery Charger.
11, 12	SW1A, SW1B	Switching Node for the Battery Charger.
13, 14	VBUSA, VBUSB	Power Connection to USB Bus Voltage.
15	SW4	Switching Node for the Boost Regulator.
16	PGND4	Power Ground for the Boost Regulator.
17	VOUT4	Power Output for the Boost Regulator.
18	FB4	Feedback Sensing Input for the Boost Regulator. In standalone mode, connect this pin to a resistor divider from V_{VOUT4}. In LED operation mode, connect FB4 to ground.
19	VIN4	Input Voltage for the Boost Regulator and LDO Control Block.
20	D1	LED 1 Sink Channel. Connect this pin to the cathode of the LED.
21	D2	LED 2 Sink Channel. Connect this pin to the cathode of the LED.
22	D3	LED 3 Sink Channel. Connect this pin to the cathode of the LED.
23	D4	LED 4 Sink Channel. Connect this pin to the cathode of the LED.
24	D5	LED 5 Sink Channel. Connect this pin to the cathode of the LED.
25	VOUT3	Power Output for LDO3.
26	CFL2	Internal Regulator Output for the Fuel Gauge. Connect a ceramic capacitor between this pin and AGND.
27	VIN123	Power Input for LDO1, LDO2, and LDO3.
28	VOUT2	Power Output for LDO2.
29	VOUT1	Power Output for LDO1.
30	SCL	I^2C Serial Clock. This pin requires an external pull-up resistor.
31	SDA	I^2C Serial Data. This pin requires an external pull-up resistor.
32	BATOK	Battery Status Open-Drain Output Flag (Active High). This pin enables the system when the battery reaches V_{WEAK}.
	EPAD	Exposed Pad (Analog Ground). The exposed pad must be connected and soldered to an external ground plane.

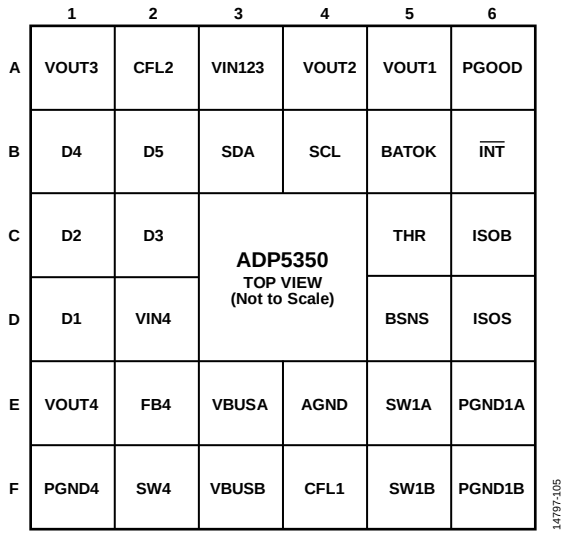


Figure 5. WLCSP Pin Configuration (Top View)

Table 10. WLCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
B6	$\overline{\text{INT}}$	Processor Interrupt (Active Low). This pin requires an external pull-up resistor. If this pin is not used, it can be left floating.
A6	PGOOD	Power-Good Signal Output. This open-drain output is the power-good signal for the selected channels.
C5	THR	Battery Pack Thermistor Connection.
D5	BSNS	Battery Voltage Sense Pin.
C6	ISOB	Battery Supply Side Input to Internal Isolation FET/Battery Current Regulation FET.
D6	ISOS	Charger Supply Side Input to Internal Isolation FET/Battery Current Regulation FET.
E4	AGND	Analog Ground.
F4	CFL1	Power input to the charger regulator. Connect a ceramic filter capacitor between this pin and either PGND1A or PGND1B.
E6, F6	PGND1A, PGND1B	Power Ground for the Battery Charger.
E5, F5	SW1A, SW1B	Switching Node for the Battery Charger.
E3, F3	VBUSA, VBUSB	Power Connection to USB Bus Voltage.
F2	SW4	Switching Node for the Boost Regulator.
F1	PGND4	Power Ground for the Boost Regulator.
E1	VOUT4	Power Output for the Boost Regulator.
E2	FB4	Feedback Sensing Input for the Boost Regulator. In standalone mode, connect this pin to a resistor divider from V_{VOUT4}. In LED operation mode, connect FB4 to ground.
D2	VIN4	Input Voltage for the Boost Regulator and LDO Control Block.
D1	D1	LED 1 Sink Channel. Connect this pin to the cathode of the LED.
C1	D2	LED 2 Sink Channel. Connect this pin to the cathode of the LED.
C2	D3	LED 3 Sink Channel. Connect this pin to the cathode of the LED.
B1	D4	LED 4 Sink Channel. Connect this pin to the cathode of the LED.
B2	D5	LED 5 Sink Channel. Connect this pin to the cathode of the LED.
A1	VOUT3	Power Output for LDO3.
A2	CFL2	Internal Regulator Output for the Fuel Gauge. Connect a ceramic capacitor between this pin and AGND.
A3	VIN123	Power Input for LDO1, LDO2, and LDO3.
A4	VOUT2	Power Output for LDO2.
A5	VOUT1	Power Output for LDO1.
B4	SCL	I^2C Serial Clock. This pin requires an external pull-up resistor.
B3	SDA	I^2C Serial Data. This pin requires an external pull-up resistor.
B5	BATOK	Battery Status Open-Drain Output Flag (Active High). This pin enables the system when the battery reaches V_{WEAK}.

TYPICAL PERFORMANCE CHARACTERISTICS

V_{VBUSx} = 5.0 V, V_{VIN4} = V_{VIN123} = V_{ISOS} = 3.6 V, C_{BUS} = 2.2 µF, C_3 = 10 µF, C_4 = 10 µF, C_{CFL1} = 4.7 µF, L_{OUT1} = 1.5 µH, all registers are at default values, unless otherwise noted.

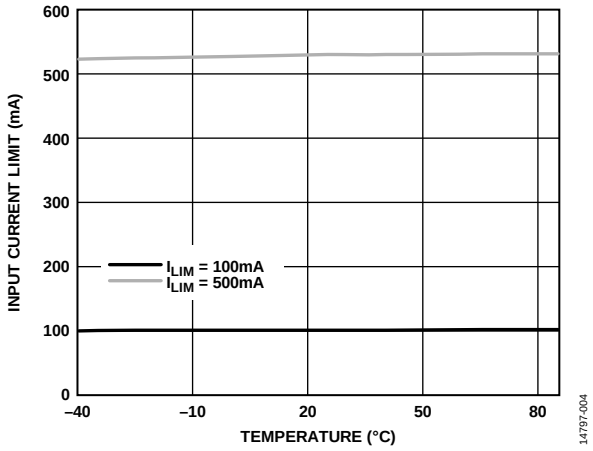


Figure 6. Input Current Limit vs. Temperature

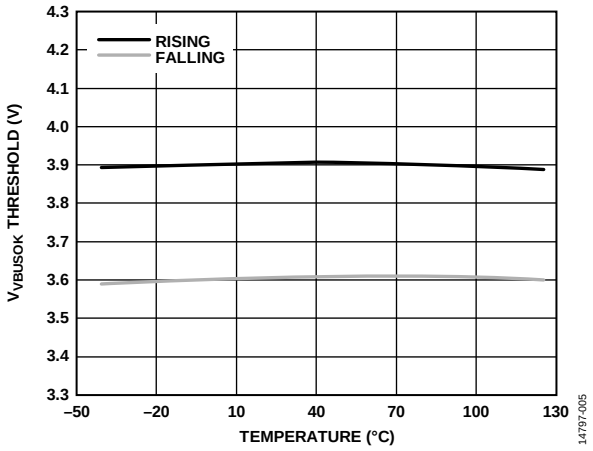


Figure 7. V_{VBUSOK} Threshold vs. Temperature

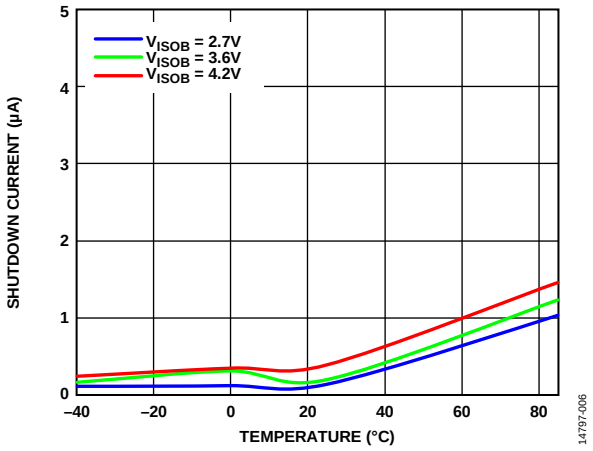


Figure 8. Shutdown Current vs. Temperature

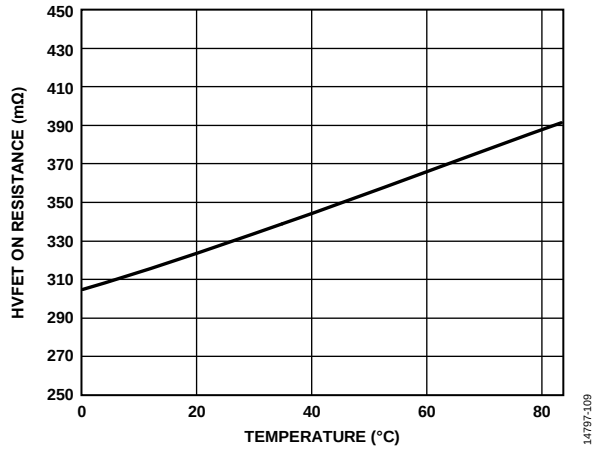


Figure 9. High Voltage FET (HVFET) On Resistance vs. Temperature

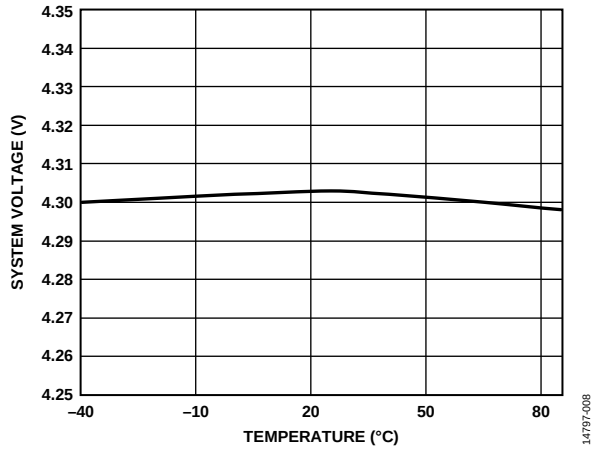


Figure 10. System Voltage vs. Temperature

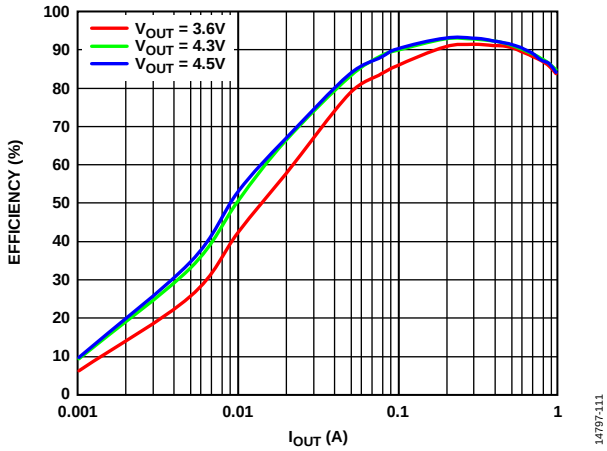


Figure 11. Efficiency vs. Ouptut Current (I_{OUT}), Buck Regulator Efficiency

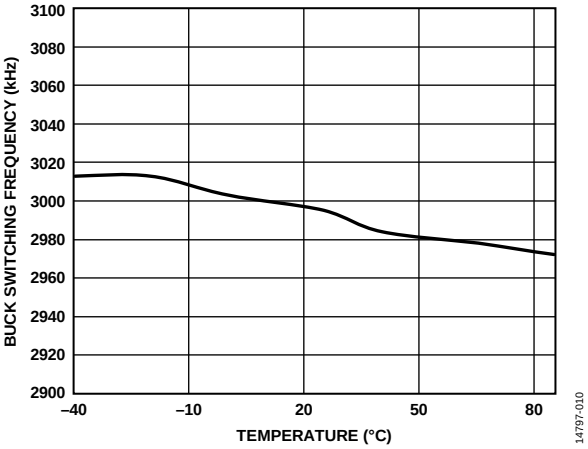


Figure 12. Buck Switching Frequency vs. Temperature

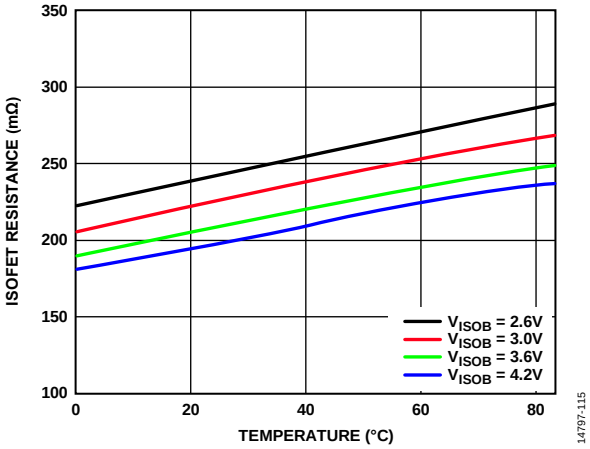


Figure 15. Isolation FET (ISOFET) Resistance vs. Temperature at Various Battery Voltage Levels, LFCSP Package

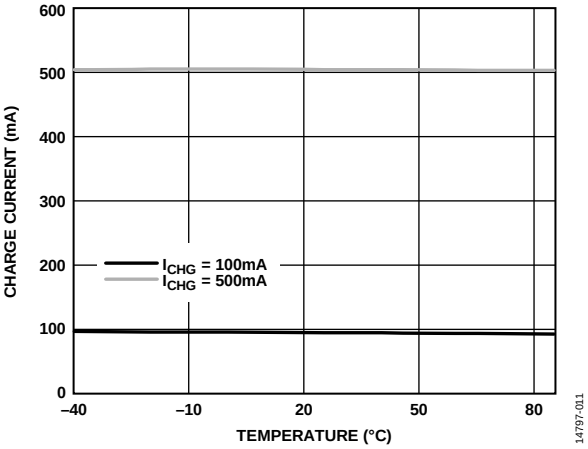


Figure 13. Charge Current vs. Temperature

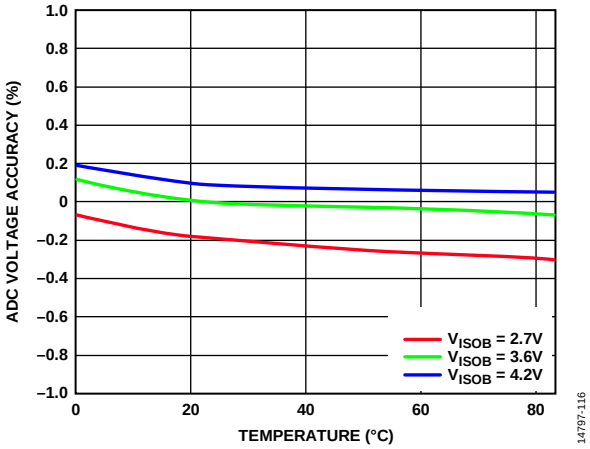


Figure 16. ADC Voltage Accuracy vs. Temperature

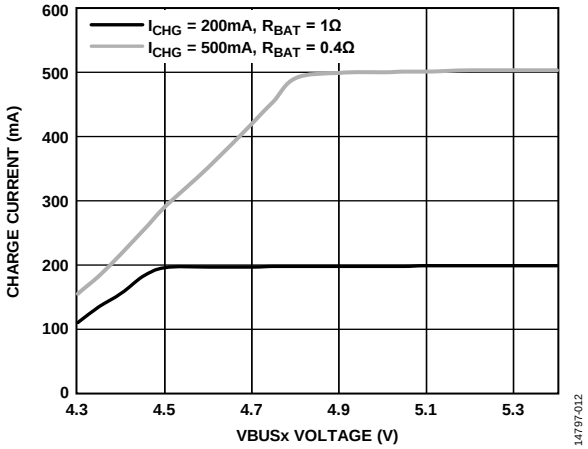


Figure 14. Charge Current vs. VBUSx Voltage

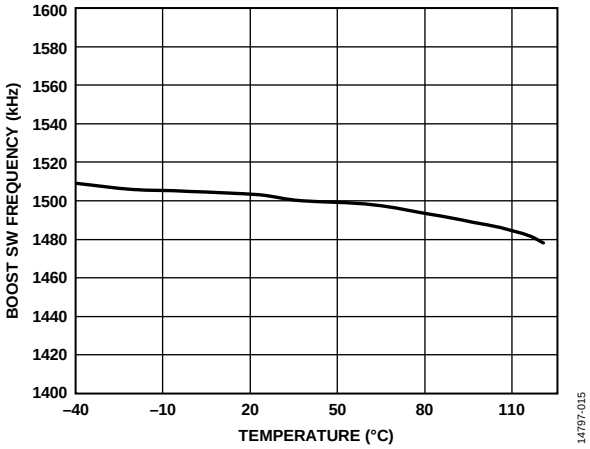


Figure 17. Boost Switching Frequency vs. Temperature

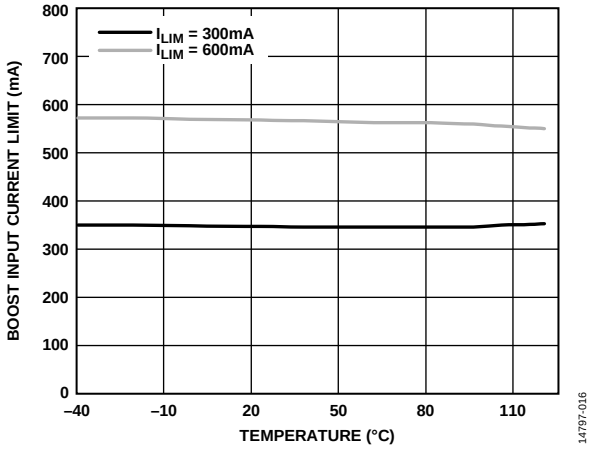


Figure 18. Boost Input Current Limit vs. Temperature

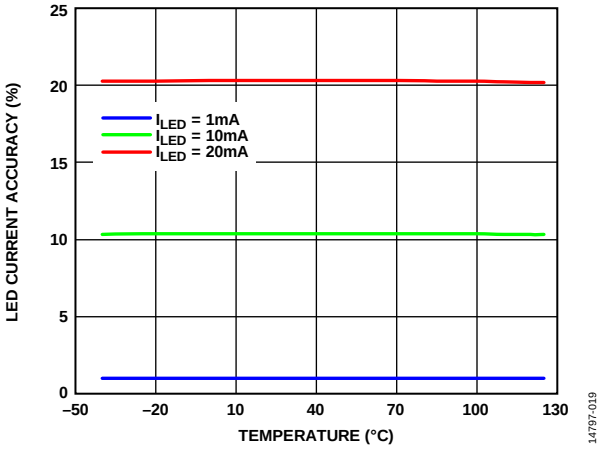


Figure 21. LED Current Accuracy vs. Temperature

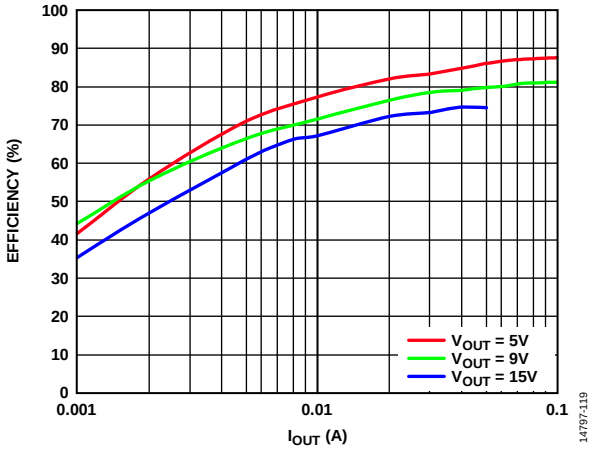


Figure 19. Boost Efficiency vs. Output Current (I_{OUT})

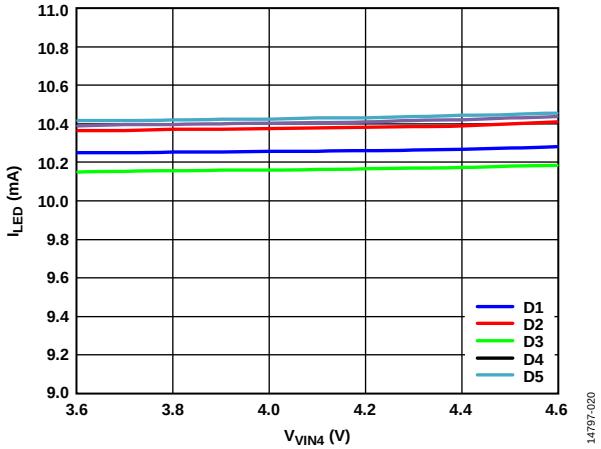


Figure 22. LED Channel Current (I_{LED}) vs. V_{VIN4}

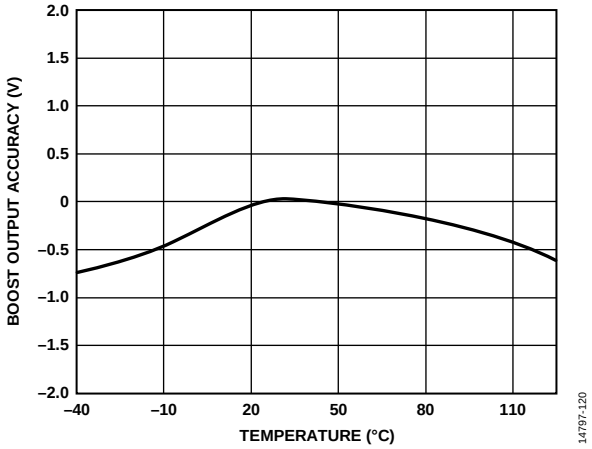


Figure 20. Boost Output Accuracy vs. Temperature, V_{VOUT4} = 5 V

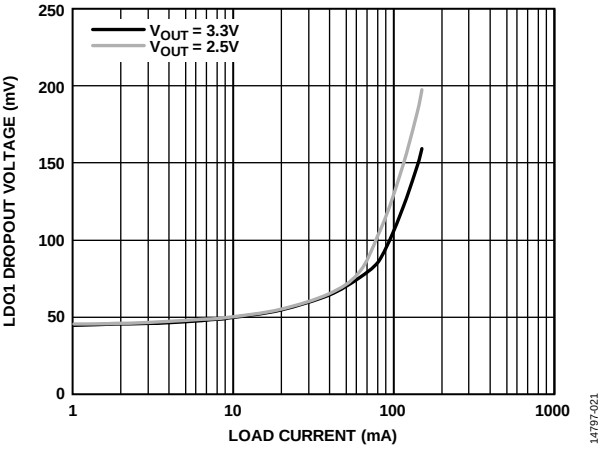


Figure 23. LDO1 Dropout Voltage vs. Load Current, LFCSP Package

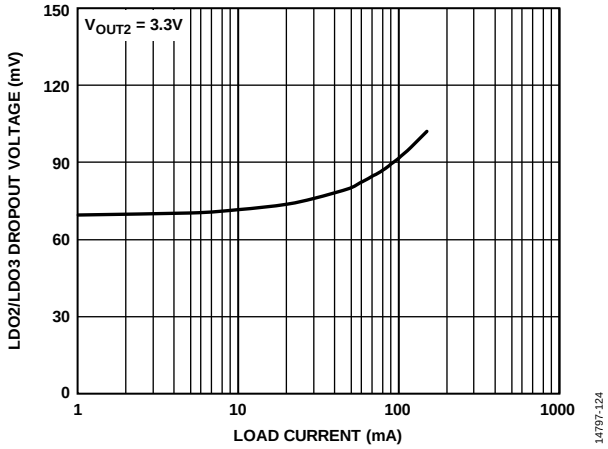


Figure 24. LDO2/LDO3 Dropout Voltage vs. Load Current, LFCSP Package

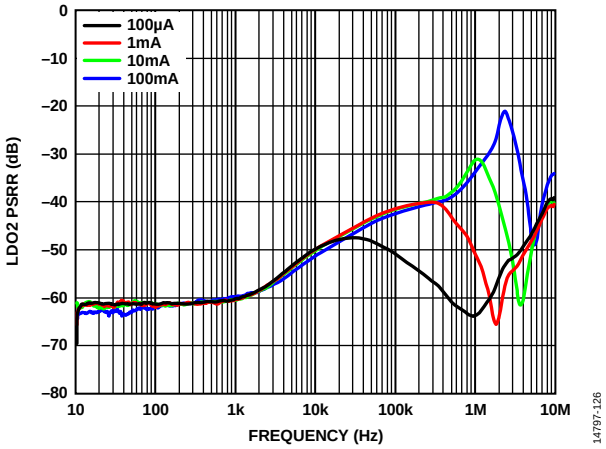


Figure 26. LDO2 Power Supply Rejection Ratio (PSRR) vs. Frequency, V_{VOUT2} = 3.3 V, V_{IN123} = 3.6 V

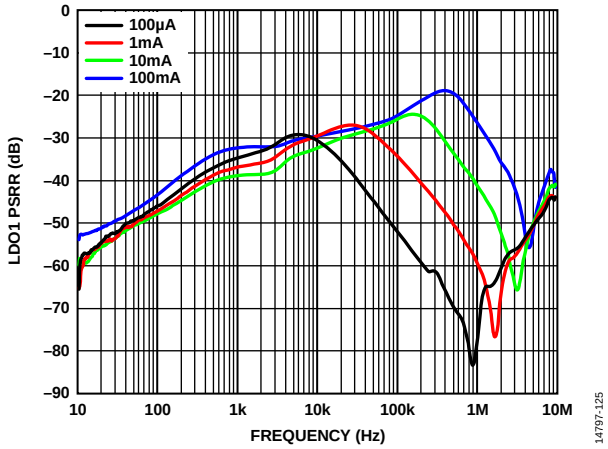


Figure 25. LDO1 PSRR vs. Frequency, V_{VOUT1} = 3.3 V, V_{VIN123} = 3.6 V

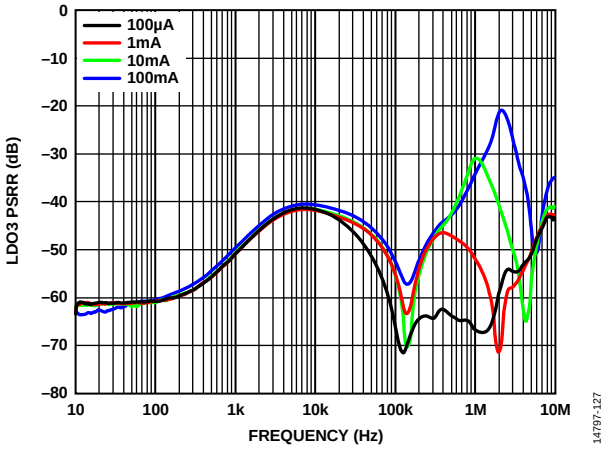


Figure 27. LDO3 PSRR vs. Frequency, V_{VOUT3} = 3.3 V, V_{IN123} = 3.6 V

TYPICAL WAVEFORMS

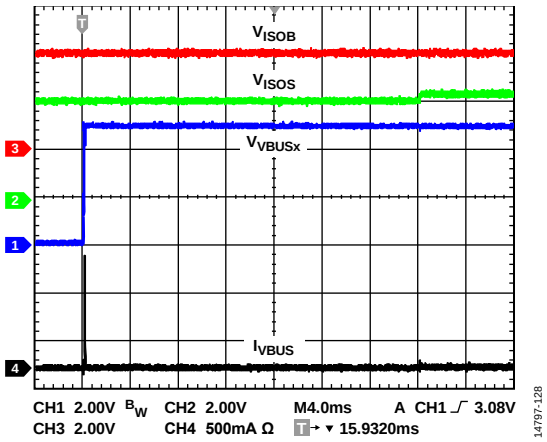


Figure 28. VBUSx Connected to USB Power

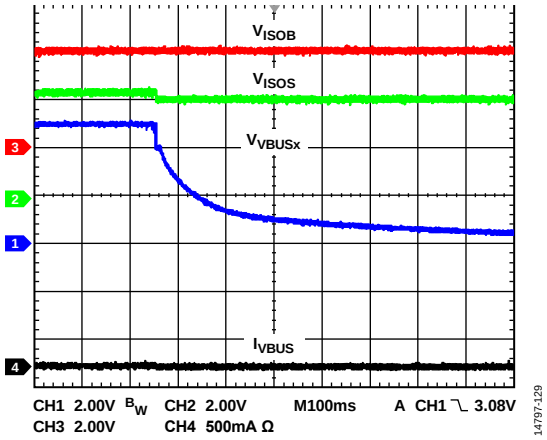


Figure 29. VBUSx Disconnected from USB Power

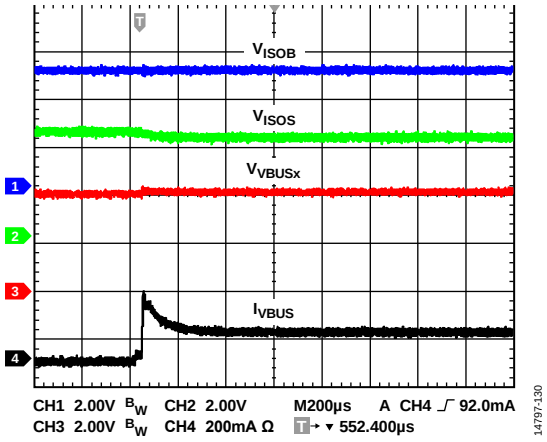


Figure 30. Charger Start with EN_CHG Set High, I_{LIM} = 500 mA, I_{CHG} = 150 mA, V_{VBUSx} = 5 V

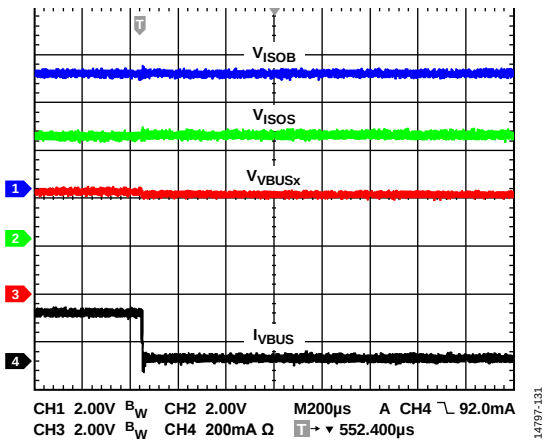


Figure 31. Charger Stop with EN_CHG Set Low, I_{LIM} = 500 mA, I_{CHG} = 200 mA, V_{VBUSx} = 5 V

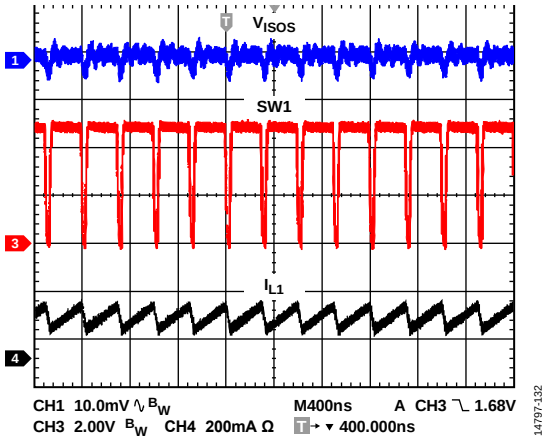


Figure 32. Fast Charger Status, I_{CHG} = 200 mA, V_{VBUSx} = 5 V

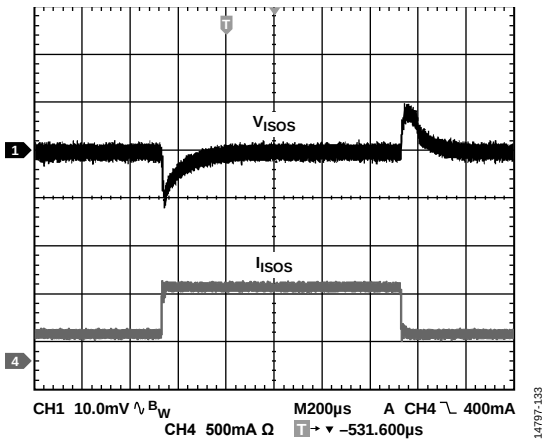


Figure 33. V_{ISOS} Voltage Load Transient Response, V_{ISOS} = 4.3 V, V_{VBUSx} = 5 V,

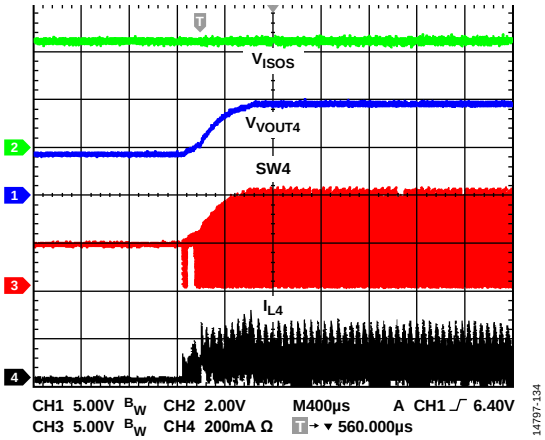


Figure 34. Boost Voltage Soft Start, LED Mode; $I_{LED1} = I_{LED2} = I_{LED3} = 10$ mA

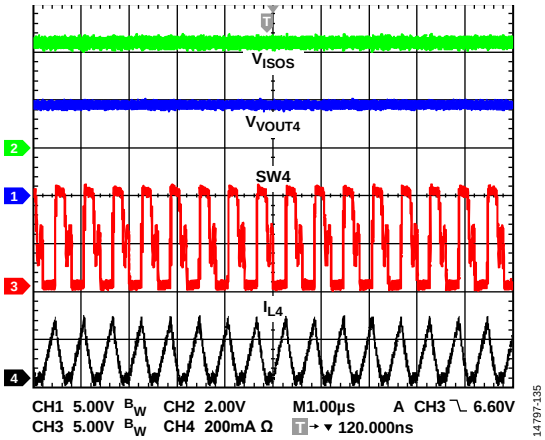


Figure 35. Boost Operation, LED Mode; $I_{LED1} = I_{LED2} = I_{LED3} = 10$ mA

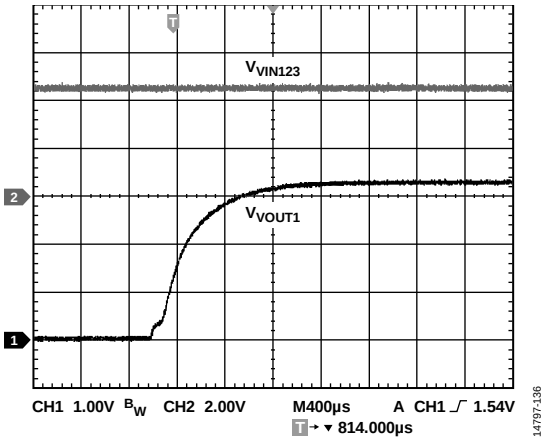


Figure 36. LDO1 Output Soft Start, $R_{LDO1} = 330\ \Omega$

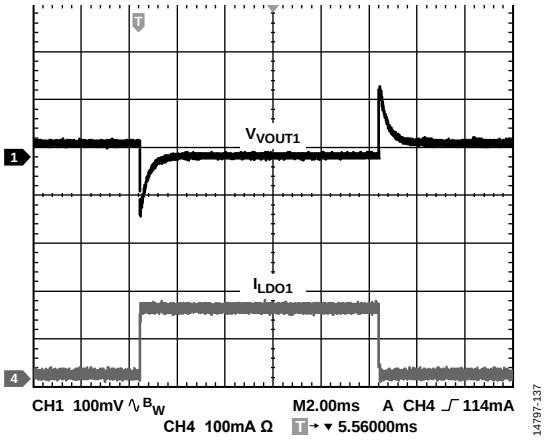


Figure 37. LDO1 Output Load Transient Response

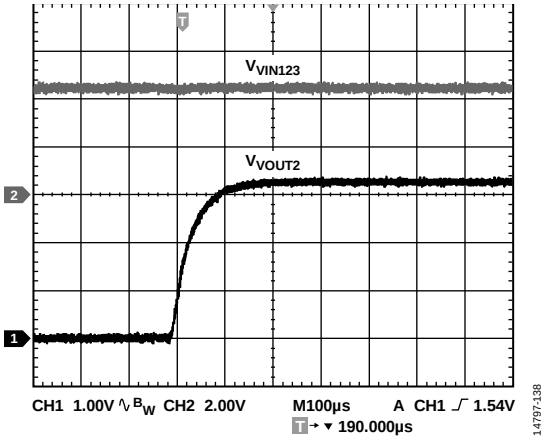


Figure 38. LDO2 Output Soft Start, $R_{LDO1} = 330\ \Omega$

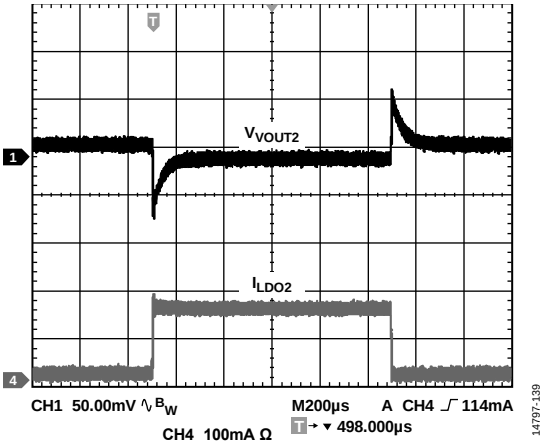


Figure 39. LDO2 Output Load Transient Response

THEORY OF OPERATION

BATTERY CHARGER OVERVIEW

The ADP5350 integrates a fully I²C-programmable charger for single-cell Li-Ion or Li-Ion polymer batteries suitable for a wide range of portable applications.

Figure 40 shows the complete charge cycle of the ADP5350 when VBUSx is connected. The ISOS pin voltage remains at V_{ISOS_TRK} when the device is not charging or when it is in trickle charge mode. When the device begins a fast charge, the V_{ISOS} voltage follows the battery voltage until the charge is complete. The charge current keeps constant in CC mode and reduces to I_{END} in CV mode. When the battery voltage, V_{ISOB}, drops to $V_{TRM} - V_{RCH}$, the charger resumes to charge until the charge completes.

The highly efficient switch dc-to-dc architecture enables higher charging currents as well as a lower temperature charging operation that results in faster charging times.

The charger of the ADP5350 operates from an input voltage from 4 V to 5.4 V but is tolerant of voltages of up to 20 V. This tolerance alleviates concerns about USB bus spiking during disconnection or connection.

The ADP5350 features an internal FET between the dc-to-dc charger output and the battery. This FET permits battery isolation and, therefore, system powering in a dead battery or no battery scenario, which allows immediate system function upon connection to a USB power supply.

The charger of the ADP5350 is fully compliant with the USB 3.0 specification and enables charging via the mini USB VBUSx pin from a wall charger, car charger, or USB host port. Based on the type of USB source, which is detected by an external USB detection device, the ADP5350 can be set to apply the correct current limit for optimal charging and USB compliance. The USB charger permits correct operation under all USB compliant sources, such as wall chargers, host chargers, hub chargers, and standard hosts and hubs.

A processor is able to control the USB charger using the I²C to program the charging current and numerous other parameters, including

- Trickle charge current level and voltage threshold
- Fast charge (CC) current level
- Fast charge (CV) voltage level
- Fast charge safety timer period
- Watchdog safety timer parameters
- Weak battery threshold detection
- End of charge current level for charge complete
- Recharge threshold
- VBUSx input current limit
- Charge enable and disable

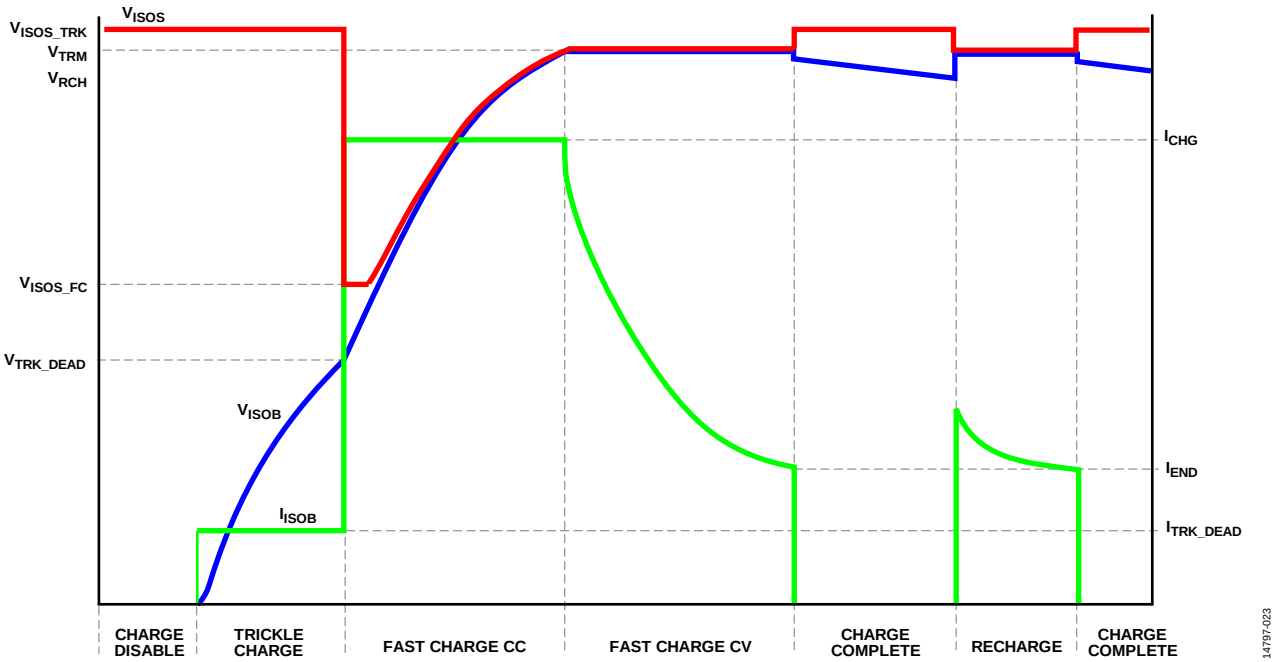


Figure 40. ADP5350 Battery Charging Profile

CHARGER MODES

Input Current Limit

The ADP5350 features a programmable input current limit, from 100 mA to 1500 mA, via the ILIM[3:0] I²C bits, which ensures compatibility with the USB limits requirements listed in Table 11. The current limit defaults to 100 mA to allow compatibility with a USB host or hub that is not configured. This input current limit resets to the 100 mA default value during every power cycle on VBUSx to protect the USB port.

When the input current limit feature is used, the available input current may be too low for the charger to meet the programmed charging current, I_{CHG}, and the rate of charge is reduced. In this case, the VBUS_ILIM flag is set.

When connecting an improper voltage level to VBUSx, the dc-to-dc regulator shuts down, the ISOFET turns on, and the high voltage blocking part is in a state wherein it draws only 1.3 mA (typical) of current until V_{VBUSx} reaches the $V_{VBUS_OV_FALL}$ level.

The ADP5350 always monitors the V_{VBUSx} voltage when there is a proper USB power connection. The VBUSOK bit, Bit 3 in Register 0x36, indicates whether the V_{VBUSx} voltage is within V_{VBUS_OV} and V_{VBUSOK}, which can be programmed to be masked to the PGOOD pin via the VBUSOK_MASK bit in Register 0x37.

The default setting of the VBUSOK_MASK is programmed via a factory fuse trim.

Trickle Charge Mode

A deeply discharged Li-Ion cell may exhibit a very low cell voltage, making it unsafe to charge the cell at high current rates. The ADP5350 charger uses a trickle charge mode to reset the battery pack protection circuit and lift the cell voltage to a safe level for fast charging. A cell with a voltage below V_{TRK_DEAD} is charged with the trickle mode current, I_{TRK_DEAD}. During trickle charge mode, the CHARGER_STATUS[3:0] bits are set.

During trickle charging, the ISOS node is regulated to V_{ISOS_TRK} by the dc-to-dc regulator and the battery isolation FET is off, which means the battery is isolated from the system power supply.

The enable of the trickle charging function is controlled via the I²C EN_TRK bit.

Trickle Charge Mode Timer

The duration of trickle charge mode is monitored to ensure the battery is revived from its deeply discharged state. If trickle charge mode runs for longer than 60 minutes without the cell voltage reaching V_{TRK_DEAD}, a fault condition is assumed and the charging stops. The battery isolation FET turns on and the dc-to-dc regulator stops working. The fault condition is asserted in the CHARGER_STATUS register, allowing the user to initiate the fault recovery procedure specified in the Fault Recovery section.

Weak Charge Mode (Constant Current)

When the battery voltage exceeds V_{TRK_DEAD} but is less than V_{WEAK}, the charger switches to weak charge mode and the ISOS node is regulated to V_{ISOS_FC} by turning on the battery isolation FET.

In weak charge mode, the battery charges with the programmed I_{CHG} current from the ISOS node through the isolation FET and trickle charge current, I_{TRK_DEAD}. Due to the VBUSx input current limit, the real I_{CHG} charge current from the ISOS node may be less than the programmed value. The system load can also share the current from the ISOS node. However, the trickle charge current, I_{TRK_DEAD}, remains on to charge the battery in weak charge mode.

Fast Charge Mode (Constant Current)

When the battery voltage exceeds V_{TRK_DEAD} and V_{WEAK}, the charger switches to fast charge mode, charging the battery with the constant current, I_{CHG}. During fast charge mode (CC), the CHARGER_STATUS[3:0] bits are set.

During CC mode, other features may prevent the current, I_{CHG}, from reaching its full programmed value. Isothermal charging mode or input current limiting for USB compatibility may affect the value of I_{CHG} under certain operating conditions. The voltage on ISOS is regulated to stay at V_{ISOS_FC} by the battery isolation FET when $V_{ISOB} < V_{ISOS_FC}$.

Fast Charge Mode (Constant Voltage)

As the battery charges, its voltage rises and approaches the termination voltage, V_{TRM}. The ADP5350 charger monitors the voltage on the BSNS pin to determine when charging ends. However, the internal ESR of the battery pack combined with PCB and other parasitic series resistances creates a voltage drop between the sense point at the BSNS pin and the cell terminal itself. To compensate for this and ensure a fully charged cell, the ADP5350 enters a constant voltage charge mode when the BSNS voltage reaches the termination voltage. The ADP5350 reduces charge current gradually as the cell continues to charge, maintaining a voltage of V_{TRM} on the BSNS pin. During fast charge mode (constant voltage), the CHARGER_STATUS[3:0] bits are set.

Fast Charge Mode Timer

The duration of fast charge mode is monitored to ensure that the battery is charging correctly. If the fast charge mode runs for longer than t_{CHG} without the voltage at the BSNS pin reaching V_{TRM}, a fault condition is assumed and charging stops. The battery isolation FET remains on, and the dc-to-dc regulator shuts down. The fault condition is asserted on the CHARGER_STATUS register, allowing the user to initiate the fault recovery procedure specified in the Fault Recovery section.

If the fast charge mode runs for longer than t_{CHG}, and V_{TRM} is reached on the BSNS pin but the charge current is not yet below I_{END}, charging stops by turning the battery isolation FET off, but the system voltage is maintained at V_{ISOS_TRK} by the dc-to-dc regulator. No fault condition is asserted in this circumstance, and the ADP5350 transitions to charge complete status.

Table 11. Input Current Compatibility with Standard USB Limits

Mode	Standard USB Limit	ADP5350 Function
USB 2.0	100 mA limit for standard USB host or hub 500 mA limit for standard USB host or hub	100 mA input current limit or I²C programmed value 500 mA input current limit or I²C programmed value
USB 3.0	150 mA limit for super speed USB 3.0 host or hub 900 mA limit for super speed, high speed USB host or hub charger	150 mA input current limit or I²C programmed value 900 mA input current limit or I²C programmed value
Dedicated Charger	1500 mA limit for dedicated charger or low/full speed USB host or hub charger	1500 mA input current limit or I²C programmed value

Watchdog Timer

The ADP5350 charger features a programmable watchdog timer function to ensure charging is under the control of the processor. The watchdog timer starts running when the ADP5350 charger determines that the processor is operational, that is, when the processor sets the RESET_WD bit for the first time or when the battery voltage is greater than the weak battery threshold, V_{WEAK}. When the watchdog timer triggers, it must be reset regularly within the watchdog timer period, t_{WD}.

If the watchdog timer expires without being reset while in charger mode, the ADP5350 charger assumes there is a software problem and triggers the safety timer, t_{SAFE}. For more information, see the Safety Timer section. Meanwhile, the I_{LIM} current limit resets to the default value.

Safety Timer

If the watchdog timer (see the Watchdog Timer section for more information) expires while in charger mode, the ADP5350 charger initiates the safety timer, t_{SAFE}. Charging continues for a period of t_{SAFE}, and then stops. The battery isolation FET remains on while the dc-to-dc regulator shuts down. The CHARGER_STATUS[3:0] bits are then set. Resetting the charger requires VBUSx to be powered down and powered up.

Charge Complete

The ADP5350 charger monitors the charging current while in CV fast charge mode. If the current falls below I_{END} and remains below I_{END} for t_{END}, the charger is stopped by turning the battery isolation FET off, but the system voltage is maintained at V_{ISOS_TRK} by the dc-to-dc regulator and the CHDONE flag is set. If the charging current falls below I_{END} for less than t_{END} and then rises above I_{END} again, the t_{END} timer resets.

Recharge

After the detection of a complete charge, and the isolated FET turns off, the ADP5350 charger continues to monitor the BSNS pin. If the BSNS pin voltage falls below $V_{TRM} - V_{RCH}$, the charger reactivates charging. Under most circumstances, triggering the recharge threshold results in the charger entering fast charge constant current mode.

Battery Charging Enable/Disable

The ADP5350 charging function can be disabled by setting the I²C EN_CHG bit to low. If the I²C EN_CHG bit is low, the dc-to-dc regulator is still on and regulates the ISOS voltage to V_{ISOS_TRK}, the battery isolation FET turns off, and the dc-to-dc regulator provides the power for the system.

BATTERY ISOLATION FET

The ADP5350 charger features an integrated battery isolation FET for power path control. The battery isolation FET isolates a deeply discharged Li-Ion cell from the system power supply in trickle charge mode and when charging is complete, thereby allowing the system to be powered from the VBUSx node.

When the V_{VBUSx} voltage is below V_{VBUSOK_FALL}, the battery isolation FET is in full conduction mode.

The battery isolation FET is off during trickle charge mode. When the battery voltage exceeds V_{TRK_DEAD}, the battery isolation FET switches to the system voltage regulation mode and the battery isolation FET maintains the V_{ISOS_FC} voltage on the ISOS pin. When the battery voltage exceeds V_{ISOS_FC}, the battery isolation FET is in full conduction mode.

The battery isolation FET supplements the battery to support high current functions on the system power supply.

When the voltage on ISOS drops below ISOB, the battery isolation FET enters full conduction mode.

When the voltage on ISOS rises above ISOB, the isolation FET enters regulating mode or full conduction mode, depending on the Li-Ion cell voltage and the dc-to-dc charger mode.

BATTERY DETECTION

Battery Level Detection

The ADP5350 charger features a battery detection mechanism to detect an absent battery. The charger actively sinks and sources current into the ISOB/BSNS node when the enable charger and V_{VBUSx} have reached the V_{VBUSOK_RISE} level, and voltage vs. time is detected. The sink phase is used to detect a charged battery, whereas the source phase is used to detect a discharged battery.

The sink phase (see Figure 41) sinks I_{SINK} current from the ISOB and BSNS pin for a time, t_{BATOK}. If the BSNS pin is below V_{BATL} when the t_{BATOK} timer expires, the charger assumes no battery is present or battery is shorted, and starts the source phase. If the BSNS exceeds the V_{BATL} voltage when the t_{BATOK} timer expires, the charger assumes the battery is present and begins a new charge cycle.

The source phase sources I_{SOURCE} current to ISOB or the BSNS pin for a time, t_{BATOK}. If the BSNS pin exceeds V_{BATH} before the

t_{BATOK} timer expires, the charger assumes that no battery is present. If the BSNS does not exceed the V_{BATH} voltage when the t_{BATOK} timer expires, the charger assumes that a battery is present, and begins a new charge cycle.

When the ADP5350 battery monitor is enabled and detects that the battery voltage is higher than V_{WEAK}, Bit 2 in Register 0x36, BATOK, asserts high. The PGOOD pin can be programmed to mask BATOK, which indicates whether the battery voltage is higher than V_{WEAK}.

Battery (ISOB) Short Detection

A battery short occurs under a damaged battery condition or when the battery protection circuitry is enabled.

After a source phase, if the voltage on ISOB or BSNS remains below V_{BATH}, either the battery voltage is low or the battery node is shorted. When the battery voltage is low, trickle charge mode is initiated (see Figure 42). If the voltage on BSNS remains below V_{BAT_SHR} after t_{BAT_SHR} has elapsed, the ADP5350 assumes that the battery node is shorted. A fault is declared on Register 0x0A, Bit 3.

The trickle charge branch is active during the battery short scenario, and trickle charge current to the battery is maintained until the 60 minutes of the trickle charge mode timer expires.

BATTERY TEMPERATURE

Battery Pack Thermistor Input

The ADP5350 charger features battery pack temperature sensing that precludes charging when the battery pack temperature is outside the specified range. The THR pin provides an on and off switching current source, which must be connected directly to the battery pack thermistor, R_{NTC}. The activation interval of the THR current source is 167 ms.

The battery pack temperature sensing can be controlled by I²C using the conditions shown in Table 12. Note that the I²C register default setting for EN_THR (Register 0x07) is 0 = temperature sensing off.

Table 12. THR Input Function

Conditions		
VBUSx	**V_{ISOB}**	**THR Function**
Open or V_{BUS} = 0 V to 4.0 V	<2.5 V	Off
Open or V_{BUS} = 0 V to 4.0 V	>2.5 V	Controlled by I²C
V_{BUS} = 4.0 V to 5.5 V	Don't care	Always on

If the battery pack thermistor is not connected directly to the ADP5350 THR pin, connect a 47 kΩ (tolerance ±20%) dummy resistor between THR and AGND. Leaving the THR pin open results in a false detection of the battery temperature of <0°C and charging being disabled. Alternatively, select the temperature source from the I²C interface by setting Register 0x20, Bit 6.

The ADP5350 charger suspends charging if the battery temperature is outside the range of less than 0°C or greater than 60°C. For temperatures greater than 0°C, and likewise for temperatures lower than 60°C, the THR_STATUS[2:0] bits are set accordingly. The ISOFET remains on while the dc-to-dc regulator shuts down.

The ADP5350 charger is designed for use with a negative temperature coefficient (NTC) thermistor in the battery pack with a nominal resistance value of 47 kΩ, 10 kΩ, or 100 kΩ at 25°C, which is selected via the I²C interface in Register 0x0C, Bit 4, and Register 0x3D, Bit 0. The temperature coefficient curve (beta) of R_{NTC} also can be fuse selected in the ADP5350.

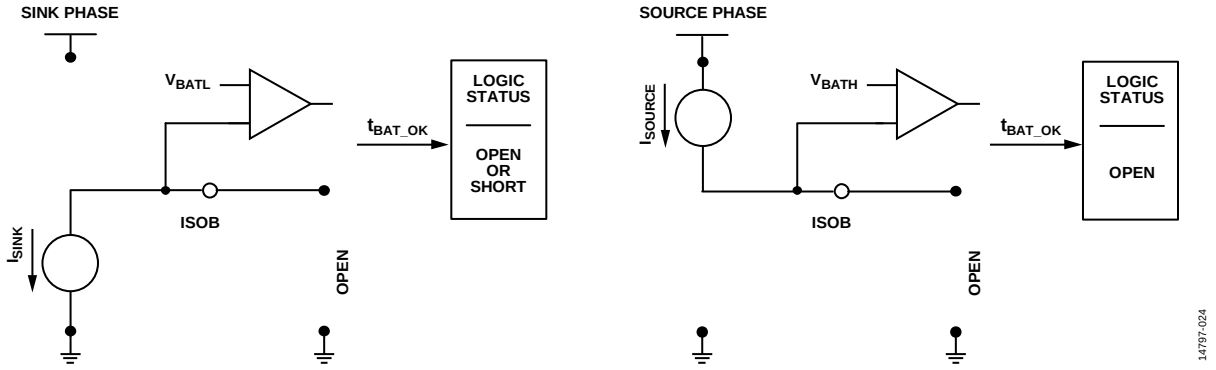


Figure 41. Battery Detection Sequence

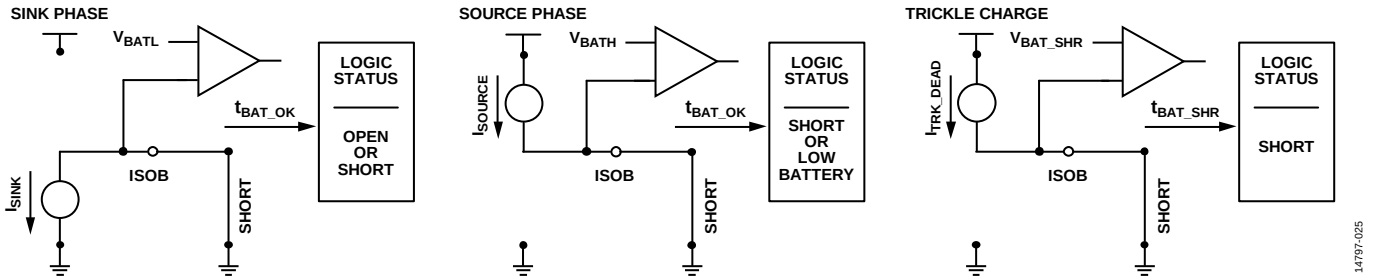


Figure 42. Battery Short Detection Sequence

Battery Temperature from I²C

If a microcontroller has another accuracy temperature sense in system, it can select the temperature source via the I²C setting and write the temperature value to the BAT_TEMP[5:0] bits. The I²C source battery temperature range is between −2°C and +61°C.

JEITA Li-Ion Battery Temperature Charging Specification

The charge of the ADP5350 is compliant with the JEITA Li-Ion battery charging temperature specifications, as shown in Table 14.

The JEITA function is enabled via the I²C interface. When the ADP5350 detects a JEITA cool condition, charging current is reduced according to Table 13.

When the ADP5350 identifies a hot or cold battery condition, the battery isolation FET turns on and the dc-to-dc regulator shuts down. In this condition, the battery provides the V_{ISOS} supply.

Table 13. JEITA Cool Temperature Limit—Reduced Charge Current Levels

	I_{CHG} JEITA (mA)	
ICHG[3:0]	ILIM_JEITA_COOL = 0	ILIM_JEITA_COOL = 1
0000 = 25 mA	25	25
0001 = 50 mA	25	25
0010 = 75 mA	25	25
0011 = 100 mA	50	25
0100 = 125 mA	50	25
0101 = 150 mA	75	25
0110 = 200 mA	100	25
0111 = 250 mA	125	25
1000 = 300 mA	150	50
1001 = 350 mA	175	50
1010 = 400 mA	200	50
1011 = 450 mA	225	50
1100 = 500 mA	250	50
1101 = 550 mA	275	50
1110 = 600 mA	300	50
1111 = 650 mA	325	50

Table 14. JEITA Default Li-Ion Battery Charging Specifications

Parameter	Symbol	Conditions	Min	Max	Unit
JEITA Cold Temperature Limits	T_{JEITA_COLD}	No battery charging occurs.		0	°C
JEITA Cool Temperature Limits	T_{JEITA_COOL}	Battery charging occurs at approximately 50% or 10% of programmed level. See Table 13 for specific charging current reduction levels.	0	10	°C
JEITA Typical Temperature Limits	T_{JEITA_TYP}	Normal battery charging occurs at default/programmed levels.	10	45	°C
JEITA Warm Temperature Limits	T_{JEITA_WARM}	Battery termination voltage (V_{TRM}) is reduced by 100 mV from the programmed value.	45	60	°C
JEITA Hot Temperature Limits	T_{JEITA_HOT}	No battery charging occurs.	60		°C

BATTERY CHARGER OPERATIONAL FLOWCHART

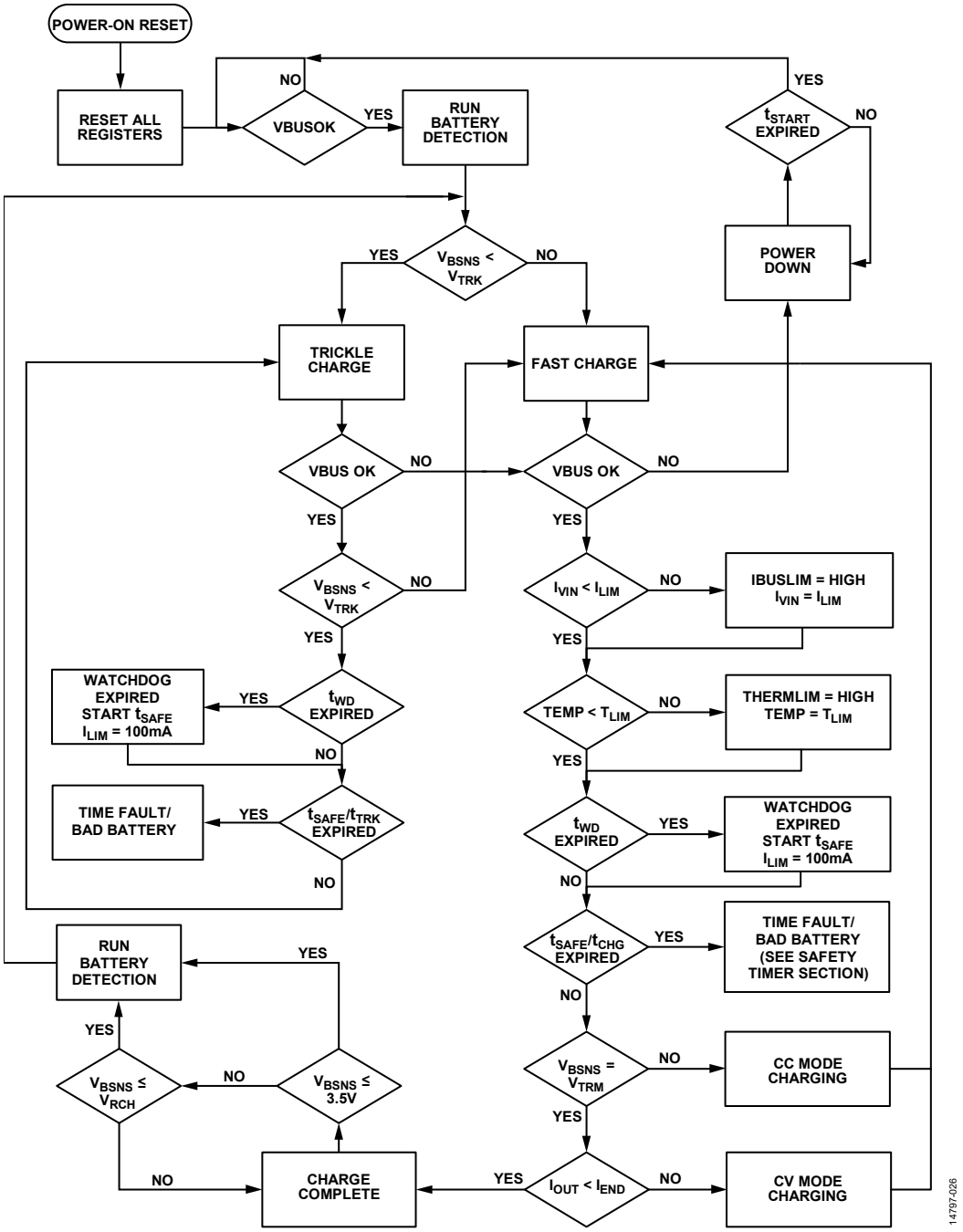


Figure 43. ADP5350 Charger Operational Flowchart

BATTERY VOLTAGE-BASED FUEL GAUGE

Overview

The ADP5350 Li-Ion battery fuel gauge is based on the voltage measurement with a 12-bit ADC. SOC is calculated with a battery model integrated in the ADP5350. Ten voltage values based on the battery characterization and the battery internal resistance at different temperatures must be written to the V_SOC_x register and RBAT_x register of the ADP5350 for SOC calculation.

Operation Mode

The ADP5350 fuel gauge, in shut down mode by default, provides extremely low standby current consumption from the battery. After the fuel gauge function is enabled, two operation modes can be selected: active mode and sleep mode. The fuel gauge operation mode is controlled by the I^2C.

In active mode, the battery SOC is updated every 1 sec by the sensed battery voltage, which achieves better accuracy and indicates the remaining battery capacity but consumes 160 µA

(typical) of operation current. In sleep mode, the battery SOC is updated every 5 min and the battery instant current (I_{INS}) is updated every 37.5 sec, which reduces the current to typically 4 µA (see Table 15). The ADP5350 automatically switches from sleep mode to active mode when the current through the isolation FET is higher than typically 35 mA. The system current must be less than 35 mA when switching to sleep mode. Depending on the system load, the mode can be switched to active mode to achieve better SOC accuracy.

Table 15. Fuel Gauge Operation Mode

Operation Mode	Current (Typical)	ADC Sample Rate	SOC Update Rate
Shutdown	0.2 µA	None	None
Sleep	4 µA	37.5 sec	5 min
Active	160 µA	0.125 sec	1 sec

Battery Voltage Compensation

The battery internal resistance impacts the accuracy of a traditional voltage-based SOC. A higher load current translates to a higher voltage drop (ΔV_{DROP}) over the internal resistance, R_{BAT} (see Figure 44).

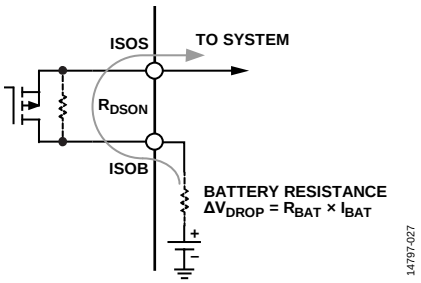


Figure 44. Discharge Current Sensing Through Battery Isolation FET

The ADP5350 uses the battery isolation FET for battery discharge current sensing. The device senses the ISOS and ISOB node voltages to obtain the delta voltage. Divide the delta voltage by R_{DSON} to achieve the discharge current, which can be used for SOC calculation compensation.

The voltage reading from the BSNS pin is compensated using the following equation and can be read in the VBAT_READ_H and VBAT_READ_L registers.

$$V_{BAT} = V_{BSNS} + R_{BAT} \times I_{BAT}$$

where:
V_{BSNS} is the voltage on the BSNS pin.
R_{BAT} is the internal resistance of the battery.
I_{BAT} is the current through the battery.

When the battery is charging, I_{BAT} is the charging current.

During the battery discharges, I_{BAT} is calculated by the voltage sense on the isolated FET.

The internal resistance of the battery has strong temperature dependency. Figure 45 shows the internal resistance temperature coefficient using a 280 mAh, 3.7 V Li-Ion cell battery.

The ADP5350 contains I²C registers to calculate the R_{BAT} value, where the user can program the battery internal resistance characterized from the battery at certain temperatures. The ADP5350 uses this data to calculate the battery internal resistance at different temperatures.

It is strongly recommended to use the I²C bits, BAT_TEMP, to obtain an accurate battery temperature if the system has such temperature sense information. If using the ADP5350 internal sense circuitry as the temperature source, only four temperature levels for battery resistance compensation are available, which may cause errors in the SOC calculation relating to the battery resistance temperature coefficient.

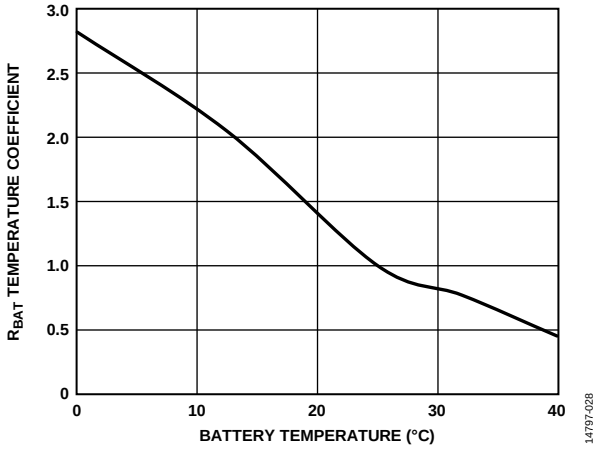


Figure 45. R_{BAT} Temperature Coefficient vs. Battery Temperature, Temperature Coefficient of the Li-Ion Battery, Relative to Battery R_{BAT} at 25°C

In addition, the internal resistance of the battery has a remaining capacity dependency, especially when the SOC is less than 20%. The ADP5350 allows the user to program different internal resistance coefficients when the SOC is in the 20% to 0% range during a discharge by programming the corresponding bits, K_RBAT_SOC (see Figure 46).

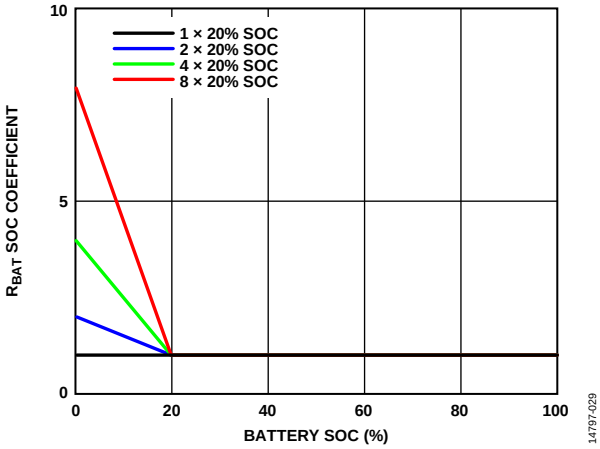


Figure 46. R_{BAT} SOC Coefficient vs. Battery SOC, SOC Coefficient of the Li-Ion Battery, Relative to Battery R_{BAT} at 25°C

For some batteries, the internal resistance is different when the battery is in charge vs. discharge mode. Use the K_RBAT_CHARGE bits to program the battery internal resistance coefficient when charging.

State of Charge Limit Filter

To avoid impacting SOC accuracy caused by the effects of a battery discharge and the instantaneous interference on the battery current sense, the ADP5350 uses filter limitation for delta SOC calculation of each step. The filter limitation can be selected from a 0.125 C rate to a 3 C rate via I²C programming, which is equal to or greater than real system current consumption (the C rate is the battery charge or discharge current rate over the battery capacity). For example, when the full system load is 60 mA with 300 mAh, and the discharge current rate is 0.2 C, the filter limitation can be programmed to 0.25 C using the FILTER_DISCHARGE bits.

When the fuel gauge is enabled, the SOC value is reset based on the current battery voltage and internal resister compensation, without any initial filter effects. Repeatedly disabling and enabling the fuel gauge or setting Register 0x25, Bit 7 to reset the SOC value during a battery discharge increases errors in SOC calculation. It is recommended that the SOC be reset only when there is no discharge current and the battery voltage is in a completely relaxed state; that is, the battery voltage is stable.

During sleep mode, the filter limitation is reduced because the ADP5350 outputs a low discharge current.

FLOWCHART OF SOC CALCULATION

See Figure 47 for a flowchart of the SOC calculation. Down_Lim is the delta SOC in each step when the SOC reduces. Up_Lim is the delta SOC in each step when the SOC increases.

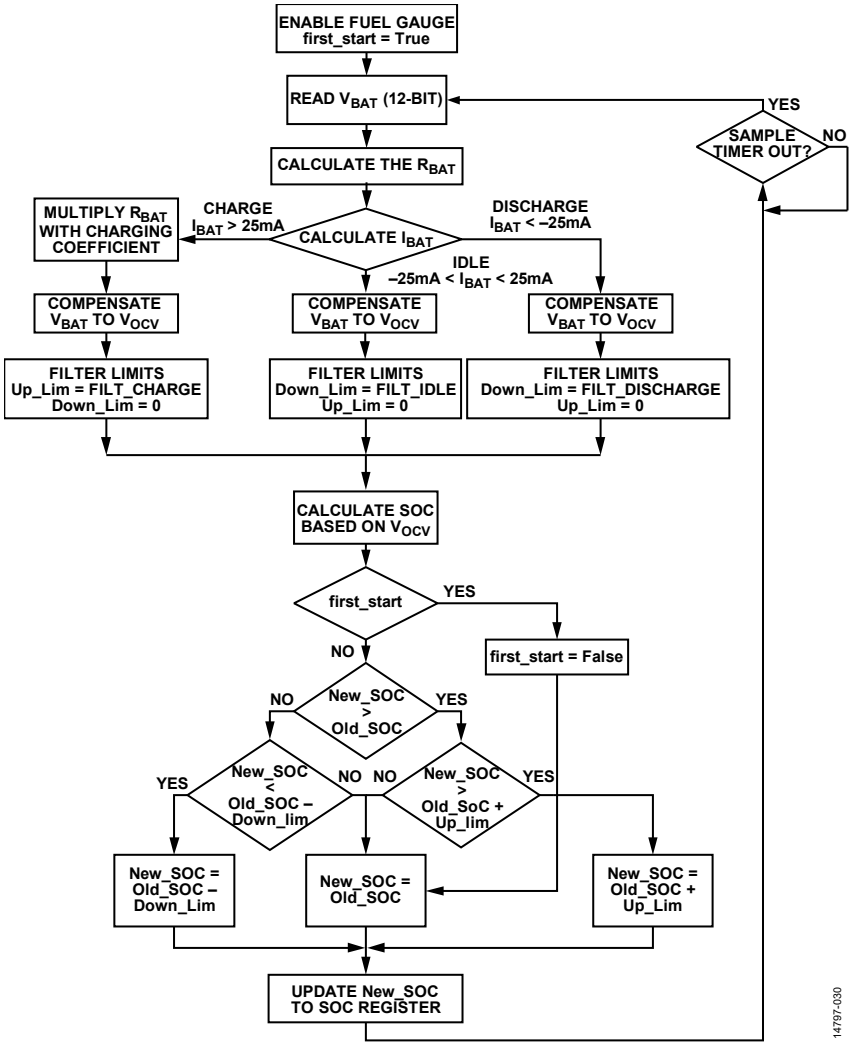


Figure 47. ADP5350 SOC Calculation Flowchart

BOOST AND WHITE LED DRIVERS

The ADP5350 integrates a powerful 1.5 MHz frequency boost regulator with programmable LED control. Different LED configurations, like LEDs in parallel or LEDs in serial, are supported with careful design. Up to five LED strings are independently programmable up to 20 mA (typical) in 64 levels. All LED strings can be individually programmed or combined into a group to operate as the backlight LEDs or individual LED current sinks.

A full suite of safety features, including current-limit, overvoltage, LED open-circuit, and overtemperature protection, allows a robust and safe design. The integrated soft start limits inrush currents during start-up and restart attempts.

White LED Driver

White LEDs are common in backlighting the displays of modern portable devices. White LEDs require a high forward voltage, V_F (typically 3.3 V), before conducting current and emitting light. Display panels, depending on the size, can be backlit with multiple white LEDs in series or in parallel. The LEDs need a common current passing through all of them to achieve uniform brightness. The LED, however, must be biased with a voltage greater than the sum of each LED V_F voltage before it can conduct.

The ADP5350 integrates a 1.5 MHz boost regulator to power the LED bias voltage. If the LED forward voltage plus the current sink headroom voltage is higher than the battery voltage, the boost regulator turns on. If the battery voltage is higher than the sum of the LED forward voltage plus the required current sink headroom voltage, the boost regulator operates in passthrough mode.

The ADP5350 uses an integrated negative channel field effect transistor (NFET) low-side current regulator for accurate brightness control, with up to five channels of current sink.

The ADP5350 supports setting different LED currents for each LED string. Any mismatch in the forward voltage of the LEDs translates directly to lower efficiency, as well as lower accuracy of the current for the lower voltage LED string.

The boost regulator in the ADP5350 has two operation modes, LED operation mode and boost standalone operation mode, which can be selected via the I²C-compatible interface.

LED Operation Mode

When the boost regulator is required to provide a higher output voltage to the LED bias voltage, the boost regulator must be configured in LED operation mode by setting BST_MODE = 0 in the BST_CFG register.

In LED operation mode, the boost regulator provides the adaptive LED bias voltage with adaptive headroom regulation to optimize the system efficiency against LED forward voltage variation and aging. The boost regulator is attached to the LED current source control and, therefore, is automatically activated by any active LED current source. The EN_BST bit is not effective in this mode.

Because the LED bias voltage may be coming from the battery system voltage instead of the boost output voltage (for example, LED indicators with relatively low forward voltage), those LEDs can be used in individual current sink channels by using the battery system voltage as the LED bias voltage. Use the BST_BL bit in the BST_CFG register to determine whether the bias voltage for individual current sink channels is coming from the boost regulator output or from the battery system voltage.

Write 0 to BST_BL to set the boost regulator to provide the bias voltage for all active LED channels. In this configuration, the boost regulator provides the adaptive headroom regulation according to all active LED current sources, including both backlight and individual current sinks.

Write 1 to BST_BL to set the boost regulator to provide the bias voltage only for the active LED backlight channels, excluding individual current sink. The bias voltage for an individual LED sink can be from the battery system voltage or from some other fixed rail; therefore, the headroom status in individual LED sinks does not affect the boost output regulation. BST_BL must be set to 1 when the indicator LED is connected to the battery system voltage instead of the boost output voltage; otherwise, the boost voltage may risk an overvoltage. The adaptive headroom control in the boost regulator may include individual LED channels whose bias voltage is not coming from the boost regulator.

The boost feedback pin (FB4 pin) is tied to ground in LED operation mode.

Boost Standalone Operation Mode

When the boost regulator is used to provide the fixed output voltage for other system uses, including organic light emitting diode (OLED) backlight, audio system, or other auxiliary circuitries, the boost regulator must be configured in standalone operation mode by setting BST_MODE = 1 in the BST_CFG register. It is recommended that total output power be limited below 800 mW when the boost peak current is set to 600 mA.

In standalone operation mode, the boost regulator provides the adjustable output voltage, V_{OUT4}, configured by the external resistor divider.

$$V_{OUT4} = V_{FB4} \times (R_{FB1} + R_{FB2})/R_{FB2}$$

The activation status of the boost regulator is determined by the EN_BST bit in the BST_CFG register. In boost standalone operation mode, all LED functions are turned off and not allowed.

In standalone operation mode, the boost feedback pin (FB4 pin) must be tied to the boost output through an external resistor divider.

Figure 48 shows the typical boost regulator diagram in standalone operation. Table 16 summarizes the difference between LED operation mode and standalone operation mode. Table 16 provides four programmable OVP thresholds according to the boost output voltage. The various OVP thresholds provide different internal compensation depending on the boost output voltage. It strongly recommended to select the proper OVP level related to the set output voltage.

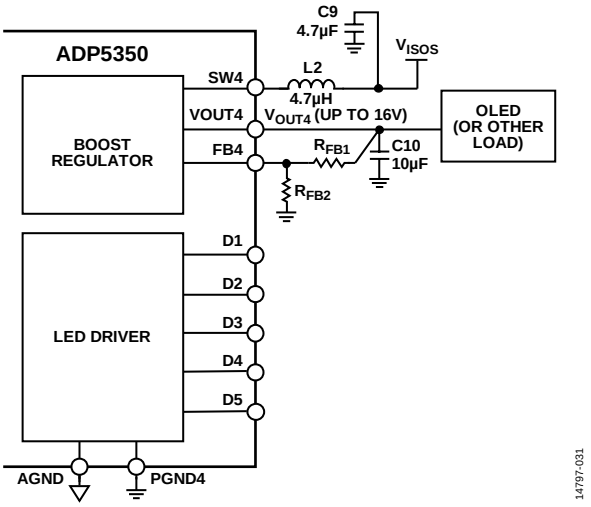


Figure 48. Boost Regulator in Standalone Operation Mode

Table 16. Two Operation Modes for the Boost Regulator

Operation	LED Operation Mode	Standalone Operation Mode
Activation Control	Activated by active LED EN_LEDx	Activated by EN_BST
Output Regulation	Adaptive to LED V_F voltage variation	Fixed and determined by external resistor divider
FB4 Pin	Tied to ground	Tied to boost output via resistor divider
OVP	5.6 V, 10 V, 15 V, or 18.5 V threshold on the VOUT4 pin	5.6 V, 10 V, 15 V, or 18.5 V threshold on the VOUT4 pin

PGOOD Indicator of Boost Output

In boost standalone mode, the PGOOD pin can be programmed to indicate whether the boost PGOOD signal is output to the external PGOOD pin by setting the PG4_BST_MASK bit high in Register 0x37. The ADP5350 monitors the FB4 pin voltage, and asserts the PGOOD signal high when the FB4 pin voltage reaches up to 90% of the typical voltage with a typical 2 ms deglitch time. The PGOOD signal asserts low when the FB4 pin voltage drops to 86.5% of the typical voltage.

The boost output PGOOD status can be read via the I^2C interface, Register 0x36, Bit 1.

Soft Start

The boost regulator in the ADP5350 includes soft start circuitry that ramps the output voltage in a controlled manner during startup, thereby limiting the inrush current of the battery. The soft start time is typically fixed at 1 ms for the boost regulator.

Backlight Current Settings

The backlight current setting is determined by a 6-bit code programmed by the user via the IBL_SET[5:0] bits. This 6-bit code allows the user to set the backlight to one of 64 levels between 0 mA and 20 mA.

The ADP5350 uses a square law algorithm for the 64 levels, where the backlight current increases linearly for a corresponding increase of input code. The backlight current, in milliamperes (mA), is determined by the following equations:

$$Backlight\ Current\ (mA) = \left(Code \times \frac{\sqrt{Full\text{–}Scale\ Current}}{63} \right)^2$$

where:
Code is the input code programmed by the user.
Full-Scale Current is the maximum sink current allowed (typically, 20 mA).

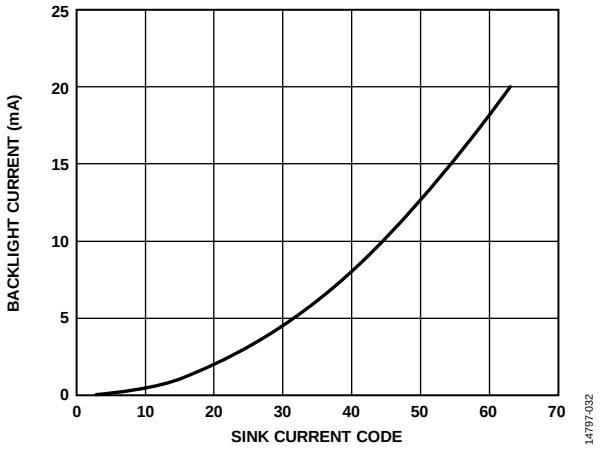


Figure 49. Backlight Current vs. Sink Current Code

Backlight Linear Fade In and Fade Out

When the ADP5350 operates in normal operation, the backlight can be turned on using the EN_BL bit. The backlight turns on when EN_BL = 1, and turns off when EN_BL = 0.

To prevent abrupt turn on and turn off of the backlight, the ADP5350 contains timers to facilitate smooth fading between the turn on and turn off states. Fading is implemented using the square law backlight code algorithm.

The BL_FI timer and BL_FO timer in the BL_FR register can be used for smooth fade in transitions from a low to high backlight setting. The BL_FI timer and BL_FO timer can be programmed to one of 15 settings ranging from 0.3 sec to 4.5 sec. The timer must be programmed before asserting EN_BL.

The time programmed in the BL_FI timer and BL_FO timer represents the time it takes the backlight current to go from 0 mA to 20 mA. Therefore, the fading time between intermediate settings is shorter. Smaller changes in current reduces the fade time. For square law fades, the fade time is given by

$$Fade\ Time = Fade\ Rate \times (Code/63)$$

where the *Fade Rate* is as shown in Table 17.

Table 17. Available Fade In and Fade Out Times

Code	Fade Rate (sec)
0000	Fade in or fade out disabled
0001	0.3
0010	0.6
0101	0.9
0110	1.2
0111	2.1
1000	2.4
1001	2.7
1010	3.0
1011	3.3
1100	3.6
1101	3.9
1110	4.2
1111	4.5

Backlight Fade Override

A fade override feature allows the BL_FI and BL_FO timers to be overridden when the EN_BL bit is reasserted during a fade in or fade out period and to set the backlight to its targeted current setting value immediately (see Figure 50). Setting the FOVR bit to 1 in the BST_CFG register enables the backlight fade override feature.

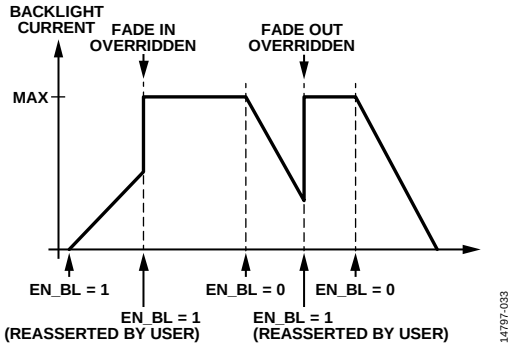


Figure 50. LED Backlight Fade Override

Independent Sink Controls

The LED current sink in Channel 2 to Channel 5 can be configured to operate as either part of a grouped backlight, or to operate as an independent LED channel.

Setting BL_LEDx = 1 configures the selected LED channel (Channel 2 to Channel 5) as the part of a grouped backlight. In this setting, the backlight current setting and on/off control in Channel 1 apply to the configured channel.

Setting BL_LEDx = 0 configures the selected LED channel (Channel 2 to Channel 5) as an independent current sink channel. Each channel current and on/off control are determined by independent register settings.

Individual LED Blinking Timer

The independent current sinks in Channel 3, Channel 4, and Channel 5 have additional timers to facilitate the blinking functions. The on timer and the off timer in the LEDx_BLINK register allow individual LED current sinks to be configured in various blinking modes. Blink mode can be activated by setting the off timers to any setting other than disabled. The blink mode setting has no effect if the channel is configured as part of a grouped backlight.

The fade in and fade out function is effective in blink mode but the fade override feature is not effective in blink mode. See Figure 51 for a timing diagram of LED blinking with fading.

Some applications (for example, red/green/blue (RGB) LEDs in blink mode) need the blinking timer to be in synchronization. If the blinking LEDs are enabled in the same I²C command, the rising time of the on timer for each blinking LED is synchronized.

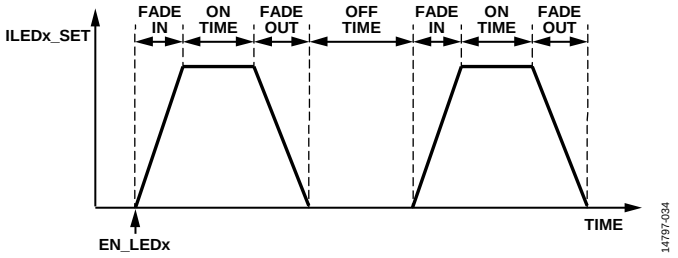


Figure 51. LED Blinking with Fading

LEDs in Parallel

Different configurations, for example, LEDs in series or LEDs in parallel, can be supported by ADP5350.

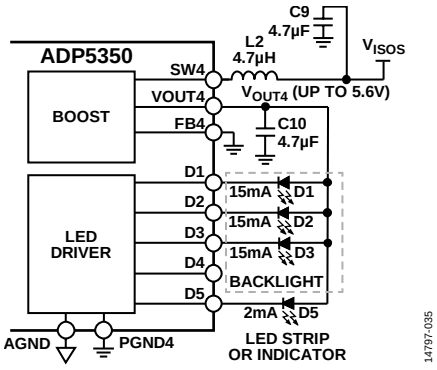


Figure 52. Thee LEDs in Parallel for Grouped Backlight and One LED Strip or Indicator

Figure 52 shows three LEDs in parallel (15 mA each), in grouped backlight configuration, connected to D1, D2, and D3, and one additional LED indicator (2 mA) connected to D5.

1. Configure the boost regulator as follows:
   a. Set BST_MODE = 0 to configure the boost regulator in LED operation mode.
   b. Set BST_BL = 0 to configure the boost regulator to provide the bias voltage to all current sink channels.
   c. Set BST_OVP = 1 to configure the boost OVP threshold = 5.6 V.
2. Configure the grouped backlight as follows:
   a. Set BL_LED2 = 1 and BL_LED3 = 1 to configure D1 to D3 as the grouped backlight.
   b. Set IBL[5:0] = 15 mA for the LED grouped backlight current.
   c. Set the BL_FI and BL_FO code for the fade in and fade out timer (if required).
   d. Set FOVR = 1 to enable the fading overwritten feature (if required).
3. Configure the individual current sink as follows:
   a. Set ILED5 = 2 mA for the D5 sink current.
   b. Set the LED5_ON and LED5_OFF code for the blinking timer (if required).
4. Set EN_BL = 1 to enable the LED backlight.
5. Set EN_LED5 = 1 to enable the LED indicator.

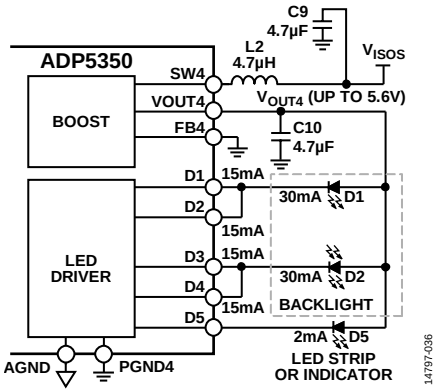


Figure 53. Two LEDs in Parallel (30 mA each) for Grouped Backlight and One LED Strip or Indicator (2 mA)

Figure 53 shows two LEDs in parallel (30 mA each), in grouped backlight configuration, connected from D1 to D4, and one additional LED indicator (2 mA) connected to D5.

1. Configure the boost regulator as follows:
   a. Set BST_MODE = 0 to configure the boost regulator in LED operation mode.
   b. Set BST_BL = 0 to configure the boost regulator to provide the bias voltage to all current sink channels.
   c. Set BST_OVP = 1 to configure the boost OVP threshold = 5.6 V. Set EN_BL bit = 1 to enable the LED backlight.
2. Configure the grouped backlight as follows:
   a. Set BL_LED2 = 1, BL_LED3 = 1, and BL_LED4 = 1 to configure D1 to D4 as the grouped backlight.
   b. Set IBL[5:0] = 15 mA for the LED grouped backlight current (two channels in parallel with 30 mA for each LED current).
   c. Set the BL_FI and BL_FO code for the fade in and fade out timer (if required).
   d. Set FOVR = 1 to enable the fading overwritten feature (if required).
3. Configure the individual current sink as follows:
   a. Set ILED5 = 2 mA for the D5 sink current.
   b. Set the LED5_ON and LED5_OFF code for the blinking timer (if required).
4. Set EN_BL = 1 to enable the LED backlight.
5. Set EN_LED5 = 1 to enable the LED indicator.

LED in Series

The ADP5350 supports connecting LEDs in series (see Figure 54 for an example).

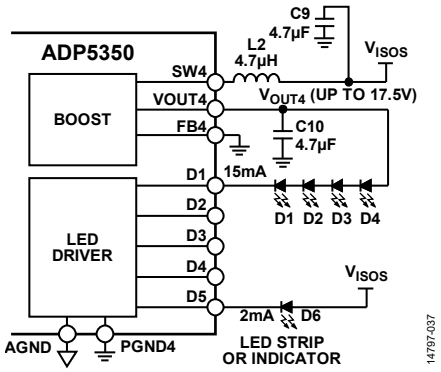


Figure 54. Four LEDs in Series (15 mA Each) for Grouped Backlight Connected to D1, and One LED Strip or Indicator (2 mA) in D5 with Connection to V_{ISOS} Rail

Figure 54 shows four LEDs in series (15 mA each), in grouped backlight configuration, connected to D1, and one additional LED indicator (2 mA) connected to D5 and the V_{ISOS} rail.

1. Configure the boost regulator as follows:
   a. Set BST_MODE = 0 to configure the boost in LED operation mode.
   b. Set BST_BL = 1 to configure the boost to provide the bias voltage to the LED backlight only.
   c. Set BST_OVP = 0 to configure the boost OVP threshold = 18.5 V.
2. Configure the grouped backlight as follows:
   a. Set IBL[5:0] = 15 mA for the LED backlight current.
   b. Set the BL_FI and BL_FO code for the fade in and fade out timer (if required).
   c. Set FOVR = 1 to enable the fading overwritten feature (if required).
3. Configure the individual current sink as follows:
   a. Set ILED5 = 2 mA for D5 sink current.
   b. Set the LED5_ON and LED5_OFF code for the blinking timer (if required).
4. Set EN_BL = 1 to enable the LED backlight.
5. Set EN_LED5 = 1 to enable the LED indicator.

Boost Switching Frequency

The boost regulator of the ADP5350 operates in 1.5 MHz fixed switching frequency and it is synchronized with the switching frequency in battery charger.

Boost Current Limit

The boost regulator in the ADP5350 includes the peak current-limit protection circuitry to limit the amount of positive current flowing through the battery to the output. Two current-limit thresholds (600 mA or 300 mA) can be selected using the BST_IPK bit. The programmable current-limit threshold feature allows the use of a small size inductor for low power applications.

As the battery discharges, the lower battery voltage results in higher peak current through the battery ESR, which may cause early shutdown of other devices on the battery. The programmable current threshold can be used to change the current limit according to different battery voltages.

Overvoltage Fault

The boost regulator contains OVP circuits to prevent damage if the V_{OUT4} voltage becomes excessive for any reason. To keep a safe output level, the integrated OVP circuit monitors the V_{OUT4} voltage. When the V_{OUT4} voltage exceeds the OVP rising threshold, the boost regulator stops switching, causing the output voltage to drop. When the V_{OUT4} voltage goes lower than the OVP falling threshold, the boot regulator begins switching, causing the output to rise. The overvoltage threshold is programmable (default of 18.5 V) in the BST_OVP register.

The overvoltage threshold level must be programmed according to the output voltage because the various OVP thresholds provide different internal compensation depending on the boost output voltage.

LED Open-Circuit Protection

The LED circuit contains a headroom control circuit to minimize power loss at each current source. Therefore, the minimum feedback voltage is achieved by regulating the output voltage of the boost regulator. If any LED string is opened during normal operation, the current source headroom voltage is pulled to AGND. In this condition, LED open-circuit protection activates when the voltage on the Dx pin is less than 200 mV and the V_{OUT4} voltage rises to the OVP level. If LED open-circuit protection is triggered, the open LED channel turns off while the other LED channel continues to work, and the LEDx_OPEN bit is set to 1 in the LED_STATUS register. The open LED channel remains disabled to ensure protection against a potential LED open circuit, until the processor clears the fault register by rewriting a 1 to the fault bit or the ADP5350 is power cycled.

When one channel is selected for independent LED operation and the bias voltage is separate from the LED backlight group (BST_BL = 1), the LED open-circuit protection has no effect on this channel due to the boost OVP never being detected on this channel.

LINEAR LOW DROPOUT (LDO) REGULATORS

The ADP5350 integrates three LDO regulators. LDO1 is a low quiescent current LDO that can be used as a supply that is always on for the system. LDO2 and LDO3 are general-purpose LDO regulators.

All LDO input power rails are supplied from the VIN123 pin and share the input power of the control circuits with the VIN4 pin. Thus, the VIN123 pin must be tied to the VIN4 pin in all applications.

The LDO regulator operates with an input voltage range of 2.7 V to 5.5 V. The wide supply range makes the regulator suitable for cascading configurations where the LDO supply

voltage is provided from the system voltage. The LDO output voltage is set by the factory fuse or I²C.

The LDO regulator provides a high power supply rejection ratio (PSRR), low output noise, and excellent line and load transient response with small 1 µF ceramic input and output capacitors.

The LDO1, LDO2, and LDO3 fixed output voltages are set by the factory fuse and include the following options: 1.0 V, 1.1 V, 1.2 V, 1.3 V, 1.4 V, 1.5 V, 1.8 V, 2.1 V, 2.3 V, 2.5 V, 2.85 V, 3.0 V, 3.15 V, 3.3 V, 3.6 V, and 4.2 V.

Load Switch Mode

All LDO regulators can be configured as a load switch via the I²C. The load switch allows power domain isolation and helps to extend the battery life.

LDO Output Discharge

Each LDO has an output discharge feature that can be selected by the I²C. When the output discharge feature is enabled, the selected LDO output connects the internal 500 Ω load to ground and pulls down the output voltage quickly when the LDO channel is disabled.

PGOOD Indicator of LDO1 Output

The ADP5350 PGOOD pin can mask various power-good channels, including LDO1, the boost regulator, and V_{VBUSx} by setting Register 0x37, Bit 0.

When the PGOOD pin masks the LDO1 power-good output and enables LDO1, the PGOOD pin indicates the LDO1 output voltage power-good signal, and asserts high when the VOUT1 pin voltage reaches up to 90% of the typical voltage with a typical 2 ms deglitch time. The PGOOD signal asserts low when the VOUT1 pin voltage drops to 86.5% of the typical voltage.

The default setting of the PG1_LDO1_MASK is a factory fuse trim that is programmable. The LDO1 power-good status can be read via the I²C interface, using Register 0x36, Bit 0.

THERMAL MANAGEMENT

Isothermal Charging and Thermal Early Warning

To assist with the thermal management of the ADP5350 charger, the battery charger provides an isothermal charging function. As the on-chip power dissipation and die temperature increase, the ADP5350 charger monitors the die temperature and limits the output current when the temperature reaches T_{SD_W}. The die temperature is maintained at T_{SD_W} through the control of the charging current into the battery. A reduction in power dissipation or ambient temperature may allow the charging current to return to its original value, and the die temperature subsequently drops below T_{SD_W}. During isothermal charging, the THERM_LIM flag is set to high.

The early warning bit is set if T_{SD_W} is exceeded. This warning bit allows the system to accommodate power consumption before thermal shutdown occurs.

Thermal Shutdown

The ADP5350 switching charger features a thermal shutdown threshold detector. If the die temperature exceeds T_{SD}, the ADP5350 charger is disabled, and the TSD_140 bit is set. The ADP5350 charger can be reenabled when the die temperature drops below the T_{SD} falling limit and the TSD_140 bit is reset. To reset the TSD_140 bit, write to the I²C Fault Register 0x0A or cycle the power.

Fault Recovery

Before performing the following operation, it is important to ensure that the cause of the fault is rectified.

To reset the fault bits in the CHARGER_FAULT register, cycle the power on VBUSx or write the corresponding I²C bit high.

I²C INTERFACE

The ADP5350 includes an I²C-compatible serial interface to control the battery charging, fuel gauge, boost regulator, and LED driver, and to read back the system status.

I²C ADDRESSES

The I²C address can be factory programmable. The I²C address options help to avoid conflicts with other I²C slave chipsets in the system. For alternative I²C chip address requirements, contact a local Analog Devices sales or distribution representative.

SDA AND SCL PINS

The ADP5350 has two dedicated I²C interface pins, SDA and SCL. SDA is an open-drain line for receiving and transmitting data. SCL is an input line for receiving the clock signal. Pull up these pins to an external input/output supply using external resistors.

Serial data is transferred on the rising edge of SCL. The read data is generated at the SDA pin in read mode.

The subaddress content selects the ADP5350 registers to be written to first. The ADP5350 sends an acknowledgement to the master after the 8-bit data byte is written (see Figure 55 for an example of the I²C write sequence to a single register). The ADP5350 increments the subaddress automatically and starts receiving a data byte at the next register until the master sends an I²C stop as shown in Figure 56.

Figure 57 shows the I²C read sequence of a single register. The ADP5350 sends the data from the register denoted by the subaddress and increments the subaddress automatically, sending data from the next register until the master sends an I²C stop condition as shown in Figure 58.

DEFAULT RESET

The ADP5350 contains one write only register, DEFAULT_SET, to reset all registers to the factory default values.

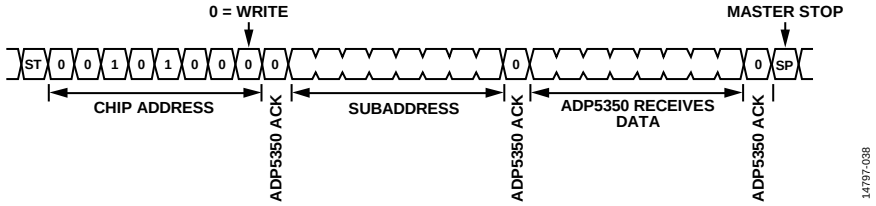


Figure 55. I²C Single Register Write Sequence

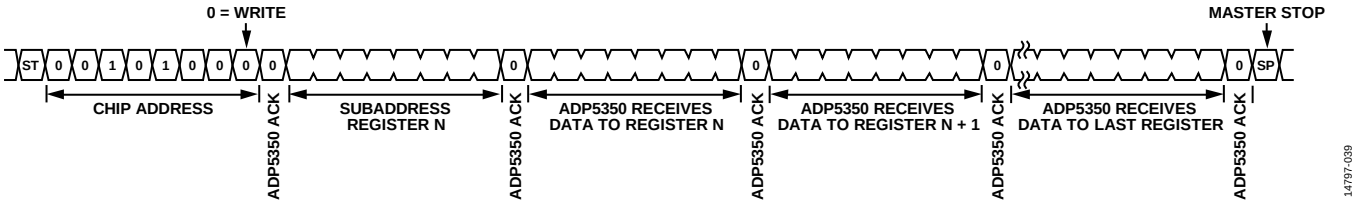


Figure 56. I²C Multiple Register Write Sequence

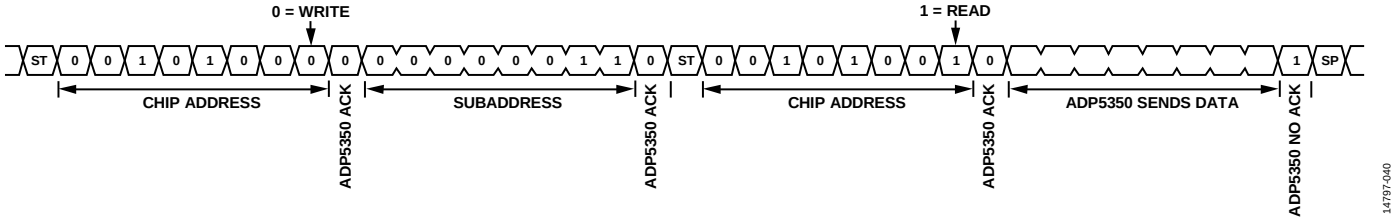


Figure 57. I²C Single Register Read Sequence

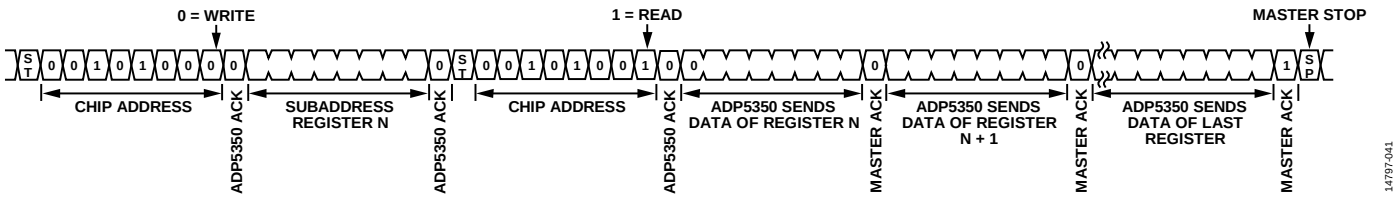


Figure 58. I²C Multiple Register Read Sequence

INTERRUPTS

The ADP5350 provides an interrupt output (the $\overline{INT}$ pin) for fault conditions. During normal operation, when the $\overline{INT}$ pin is pulled high, use an external pull-up resistor. When a fault condition occurs, the ADP5350 pulls the $\overline{INT}$ pin low to alert the I^2C host that a fault condition occurred.

Many different interrupt sources can trigger the $\overline{INT}$ pin. By default, no interrupt sources are configured. To select one or more interrupt sources to trigger the $\overline{INT}$ pin, set the appropriate bits to 1 in the CHARGER_INTERRUPT_ENABLE register and the BOOST_LDO_INTERRUPT_ENABLE register.

When the $\overline{INT}$ pin is triggered, one or more bits in the CHARGER_INTERRUPT_FLAG register and the BOOST_LDO_INTERRUPT_FLAG register are set to 1. The fault condition that triggered the $\overline{INT}$ pin can be read from the CHARGER_INTERRUPT_FLAG register and the BOOST_LDO_INTERRUPT_FLAG register.

To clear an interrupt, read the appropriate bit in the CHARGER_INTERRUPT_FLAG register and the BOOST_LDO_INTERRUPT_FLAG register, or power cycle the ADP5350.

CONTROL REGISTER MAP

Table 18. Register Map

Address (Hex)	Register Name	D7	D6	D5	D4	D3	D2	D1	D0
0x00	Manufacture and model ID	MANUF[3:0]				Model[3:0]			
0x01	Silicon revision	Not used				REV[3:0]			
0x02	CHARGER_ VBUS_ILIM	Not used				ILIM[3:0]			
0x03	CHARGER_ TERMINATION_ SETTING	VTRM[5:0]						IEND[1:0]	
0x04	CHARGER_ CURRENT_ SETTING	C_20_EOC	C_10_EOC	ICHG[3:0]				ITRK_DEAD[1:0]	
0x05	CHARGER_ VOLTAGE_ THRESHOLD	Not used	VRCH[1:0]		VTRK_DEAD[1:0]		VWEAK[2:0]		
0x06	CHARGER_ TIMER_SETTING	Not used	EN_TEND	EN_CHG_ TIMER	CHG_TMR_PERIOD		EN_WD	WD_PERIOD	RESET_WD
0x07	CHARGER_ FUNCTION_ SETTING1	EN_JEITA	DIS_IPK_SD	EN_BMON	EN_THR	EN_DCDC	EN_EOC	EN_TRK	EN_CHG
0x08	CHARGER_ STATUS1	VBUS_OV	Not used	VBUS_ILIM	THERM_ LIM	CHDONE	CHARGER_STATUS[2:0]		
0x09	CHARGER_ STATUS2	THR_STATUS[2:0]			IPK_STAT	Not used	BATTERY_STATUS[2:0]		
0x0A	CHARGER_ FAULT	Not used				BAT_SHR	IND_PEAK	TSD_130	TSD_140
0x0B	BATTERY_ SHORT	TBAT_SHR[2:0]			Not used		VBAT_SHR[2:0]		
0x0C	BATTERY_ THERMISTOR_ CONTROL	ILIM_JEITA_ COOL	TBAT_LOW	TBAT_ HIGH	R_NTC	BETA_NTC[3:0]			
0x0D	V_SOC_0	V_SOC_0[7:0]							
0x0E	V_SOC_5	V_SOC_5[7:0]							
0x0F	V_SOC_11	V_SOC_11[7:0]							
0x10	V_SOC_19	V_SOC_19[7:0]							
0x11	V_SOC_28	V_SOC_28[7:0]							
0x12	V_SOC_41	V_SOC_41[7:0]							
0x13	V_SOC_55	V_SOC_55[7:0]							
0x14	V_SOC_69	V_SOC_69[7:0]							
0x15	V_SOC_84	V_SOC_84[7:0]							
0x16	V_SOC_100	V_SOC_100[7:0]							
0x17	FILTER_ SETTING1	Not used	FILTER_CHARGE[2:0]			Not used	FILTER_DISCHARGE[2:0]		
0x18	FILTER_ SETTING2	Not used						FILT_IDLE[1:0]	
0x19	RBAT_0	RBAT_0[7:0]							
0x1A	RBAT_10	RBAT_10[7:0]							
0x1B	RBAT_20	RBAT_20[7:0]							
0x1C	RBAT_30	RBAT_30[7:0]							
0x1D	RBAT_40	RBAT_40[7:0]							
0x1E	RBAT_60	RBAT_60[7:0]							
0x1F	K_RBAT_CHARGE	Not used		K_RBAT_SOC[1:0]		K_RBAT_CHARGE[3:0]			
0x20	BAT_TEMP	Not used	BAT_TEMP_ SOURCE	BAT_TEMP[5:0]					
0x21	BAT_SOC	Not used	BAT_SOC[6:0]						
0x22	VBAT_READ_H	VBAT_READ[12:5]							
0x23	VBAT_READ_L	VBAT_READ[4:0]					Not used		

Address (Hex)	Register Name	D7	D6	D5	D4	D3	D2	D1	D0
0x24	FUEL_GAUGE_ MODE	Not used					SLEEP_ UPDATE_ TIME	FUEL_GAUGE_ MODE	FUEL_ GAUGE_ ENABLE
0x25	SOC_RESET	SOC reset	Not used						
0x26	BST_LED_CTRL	Not used		EN_BST	EN_LED5	EN_LED4	EN_LED3	EN_LED2	EN_BL
0x27	BST_CFG	BST_MODE	BST_BL	FOVR	Not used	BST_OVP		Not used	BST_IPK
0x28	IBL_SET	Not used	IBL[5:0]						
0x29	ILED2_SET	BL_LED2	Not used	ILED2[5:0]					
0x2A	ILED3_SET	BL_LED3	Not used	ILED3[5:0]					
0x2B	ILED4_SET	BL_LED4	Not used	ILED4[5:0]					
0x02C	ILED5_SET	BL_LED5	Not used	ILED5[5:0]					
0x2D	BL_FR	BL_FO[3:0]				BL_FI[3:0]			
0x2E	LED3_BLINK	LED3_OFF[3:0]				LED3_ON[3:0]			
0x2F	LED4_BLINK	LED4_OFF[3:0]				LED4_ON[3:0]			
0x30	LED5_BLINK	LED5_OFF[3:0]				LED5_ON[3:0]			
0x31	LED_STATUS	Not used			LED5_ OPEN	LED4_ OPEN	LED3_OPEN	LED2_OPEN	LED1_OPEN
0x32	LDO_CTRL	Not used					EN_LDO3	EN_LDO2	EN_LDO1
0x33	LDO_CFG	Not used	DSCG_LDO3	DSCG_ LDO2	DSCG_ LDO1	Not used	MODE_LDO3	MODE_LDO2	MODE_LDO1
0x34	VID_LDO12	VID_LDO2[3:0]				VID_LDO1[3:0]			
0x35	VID_LDO3	Not used				VID_LDO3[3:0]			
0x36	PGOOD_STATUS	Not used				VBUSOK	BATOK	PG4_BST	PG1_LDO1
0x37	PGOOD_MASK	Not used				VBUSOK_ MASK	BATOK_ MASK	PG4_BST_MASK	PG1_LDO1_ MASK
0x38	CHARGER_ INTERRUPT_ ENABLE	EN_IND_ PEAK_INT	EN_THERM_ LIM_INT	EN_WD_ INT	EN_TSD_ INT	EN_THR_ INT	EN_BAT_INT	EN_CHG_INT	EN_VIN_INT
0x39	CHARGER_ INTERRUPT_ FLAG	IND_PEAK_ INT	THERM_ LIM_INT	WD_INT	TSD_INT	THR_INT	BAT_INT	CHG_INT	VIN_INT
0x3A	BOOST_LDO_ INTERRUPT_ ENABLE	Not used					EN_LED_ OPEN_INT	EN_PG4_BST_ INT	EN_PG1_ LDO1_INT
0x3B	BOOST_LDO_ INTERRUPT_ FLAG	Not used					LED_OPEN_ INT	PG4_BST_INT	PG1_ LDO1_INT
0x3C	DEFAULT_SET	DEFAULT_SET							
0x3D	NTC47K_SET	Not used							NTC_47K

REGISTER BIT DESCRIPTIONS

Table 19. Manufacturer and Model ID, Register Address 0x00 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	MANUF[3:0]	R	0001	The 4-bit manufacturer identification bus.
[3:0]	Model[3:0]	R	1011	The 4-bit model identification bus.

Table 20. Silicon Revision, Register Address 0x01 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	Not used	R		
[3:0]	REV[3:0]	R	0011	The 4-bit silicon revision identification bus.

Table 21. CHARGER_VBUS_ILIM, Register Address 0x02 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	Not used	R		Not used.
[3:0]	ILIM[3:0]	R/W	0000	VBUSx pin input current-limit programming bus. The current into VBUSx can be limited to the following programmed values: 0000 = 100 mA. 0001 = 150 mA. 0010 = 200 mA. 0011 = 300 mA. 0100 = 400 mA. 0101 = 500 mA. 0110 = 600 mA. 0111 = 700 mA. 1000 = 800 mA. 1001 = 900 mA. 1010 = 1000 mA. 1011 = 1100 mA. 1100 = 1200 mA. 1101 = 1300 mA. 1110 = 1400 mA. 1111 = 1500 mA.

Table 22. CHARGER_TERMINATION_SETTINGS, Register Address 0x03 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:2]	VTRM[5:0]	R/W	100011	Termination voltage programming bus. The values of the float voltage can be programmed to the following values: 000000 = 3.50 V. 000001 = 3.52 V. 000010 = 3.54 V. 000011 = 3.56 V. 000100 = 3.58 V. 000101 = 3.60 V. 000110 = 3.62 V. 000111 = 3.64 V. 001000 = 3.66 V. 001001 = 3.68 V. 001010 = 3.70 V. 001011 = 3.72 V. 001100 = 3.74 V. 001101 = 3.76 V. 001110 = 3.78 V. 001111 = 3.80 V. 010000 = 3.82 V.

Bit No.	Mnemonic	Access	Default	Description
				010001 = 3.84 V. 010010 = 3.86 V. 010011 = 3.88 V. 010100 = 3.90 V. 010101 = 3.92 V. 010110 = 3.94 V. 010111 = 3.96 V. 011000 = 3.98 V. 011001 = 4.00 V. 011010 = 4.02 V. 011011 = 4.04 V. 011100 = 4.06 V. 011101 = 4.08 V. 011110 = 4.10 V. 011111 = 4.12 V. 100000 = 4.14 V. 100001 = 4.16 V. 100010 = 4.18 V. 100011 = 4.20 V. 100100 = 4.22 V. 100101 = 4.24 V. 100110 = 4.26 V. 100111 = 4.28 V. 101000 = 4.30 V. 101001 = 4.32 V. 101010 = 4.34 V. 101011 = 4.36 V. 101100 = 4.38 V. 101101 = 4.40 V. 101110 = 4.42 V. 101111 = 4.44 V. 110000 = 4.46 V. 110001 = 4.48 V. 110010 to 111111 = 4.5 V.
[1:0]	IEND[1:0]	R/W	01	Termination current programming bus. The values of the termination current can be programmed to the following values: 00 = 25 mA. 01 = 35 mA. 10 = 45 mA. 11 = 55 mA.

Table 23. CHARGER_CURRENT_SETTING, Register Address 0x04 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	C_20_EOC	R/W	0	This bit has priority over the other settings (C_10_EOC and IEND). When this bit is set to high, 1/20 C programming is used. The minimum value is 25 mA.
6	C_10_EOC	R/W	0	This bit has priority over the other setting (IEND) but not C_20_EOC. When this bit is set to high, 1/10 C programming is used unless C_20_EOC is set to high. The minimum value is 25 mA.

Bit No.	Mnemonic	Access	Default	Description
[5:2]	ICHG[3:0]	R/W	1100	Fast charge current programming bus. The values of the constant current charge can be programmed to the following values: 0000 = 25mA. 0001 = 50 mA. 0010 = 75 mA. 0011 = 100 mA. 0100 = 125 mA. 0101 = 150 mA. 0110 = 200 mA. 0111 = 250 mA. 1000 = 300 mA. 1001 = 350 mA. 1010 = 400 mA. 1011 = 450 mA. 1100 = 500 mA. 1101 = 550 mA. 1110 = 600 mA. 1111 = 650 mA.
[1:0]	ITRK_DEAD[1:0]	R/W	10	Trickle and weak charge current programming bus. The values of the trickle and weak charge currents can be programmed as per the following values: 00 = 5 mA. 01 = 10 mA. 10 = 20 mA. 11 = 50 mA.

Table 24. CHARGER_VOLTAGE_THRESHOLD, Register Address 0x05 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	Not used	R		Not used.
[6:5]	VRCH[1:0]	R/W	11	Recharge voltage programming bus. The values of the recharge threshold can be programmed as per the following values: 00 = 80 mV. 01 = 140 mV. 10 = 200 mV. 11 = 260 mV.
[4:3]	VTRK_DEAD[1:0]	R/W	01	Trickle to fast charge dead battery voltage programming bus. The values of the trickle to fast charge threshold can be programmed to the following values: 00 = 2.4 V. 01 = 2.5 V. 10 = 2.6 V. 11 = 3.3 V.
[2:0]	VWEAK[2:0]	R/W	011	Weak battery voltage rising threshold. The values of the weak battery voltage rising threshold can be programmed to the following values: 000 = 2.7 V. 001 = 2.8 V. 010 = 2.9 V. 011 = 3.0 V. 100 = 3.1 V. 101 = 3.2 V. 110 = 3.3 V. 111 = 3.4 V.

Table 25. CHARGER_TIMER_SETTING, Register Address 0x06 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	Not used	R		Not used.
6	EN_TEND	R/W	1	When low, this bit disables the charge complete timer (t_{END}), and a 31 ms deglitch timer remains on this function.
5	EN_CHG_TIMER	R/W	1	When high, the trickle/fast charge timer is enabled.
[4:3]	CHG_TMR_PERIOD	R/W	11	Trickle/fast charge timer period. 00 = 15 minutes/150 minutes. 01 = 30 minutes/300 minutes. 10 = 45 minutes/450 minutes. 11 = 60 minutes/600 minutes.
2	EN_WD	R/W	0	0 = the watchdog timer is disabled even when V_{BSNS} exceeds V_{TRK_DEAD}. 1 = the watchdog timer safety timer is enabled.
1	WD_PERIOD	R/W	0	Watchdog safety timer period. 0 = 32 sec to 40 min. 1 = 64 sec to 40 min.
0	RESET_WD	W	0	When this bit is high, the watchdog safety timer resets. This bit is reset automatically.

Table 26. CHARGER_FUNCTION_SETTING1, Register Address 0x07 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	EN_JEITA	R/W	0	When low, this bit disables the JEITA Li-Ion temperature battery charging specification.
6	DIS_IPK_SD	R/W	1	When high, this bit disables the automatic shutdown of the device if four peak inductor current limits are reached in succession. In addition, when this bit is high, it only flags the IPK_STAT status bit.
5	EN_BMON	R/W	0	When this bit is high, the battery monitor is enabled even when the voltage at the VBUSx pins is below V_{VBUSOK_FALL}.
4	EN_THR	R/W	0	When this bit is high, the THR current source is enabled even when the voltage at the VBUSx pins is below V_{VBUSOK_FALL}.
3	EN_DCDC	R/W	1	When this bit is low, the dc-to-dc converter is disabled. When this bit is high, the dc-to-dc converter is enabled.
2	EN_EOC	R/W	1	When this bit is high, end of charge is allowed.
1	EN_TRK	R/W	1	When this bit is low, trickle charger is disabled and the dc-to-dc converter is enabled.
0	EN_CHG	R/W	Factory setting	When this bit is low, charging is disabled. When this bit is high and EN_DCDC = high, charging is enabled.

Table 27. CHARGER_STATUS1, Register Address 0x08 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	VBUS_OV	R	Not applicable	When high, this bit indicates that the voltage at the VBUSx pins exceeds V_{VBUS_OV}.
6	Not used	R		Not used.
5	VBUS_ILIM	R	Not applicable	When high, this bit indicates that the current into a VBUSx pin is limited by the high voltage blocking FET and the charger is not running at the full programmed I_{CHG}.
4	THERM_LIM	R	Not applicable	When high, this bit indicates that the charger is not running at the full programmed I_{CHG} but is limited by the die temperature.
3	CHDONE	R	Not applicable	When high, this bit indicates the end of charge cycle is reached. This bit latches on, in that it does not reset to low when the V_{RCH} threshold is breached.

Bit No.	Mnemonic	Access	Default	Description
[2:0]	CHAGER_STATUS[2:0]	R	Not applicable	Charger status bus. 000 = off. 001 = trickle charge. 010 = fast charge (CC mode). 011 = fast charge (CV mode). 100 = charge complete. 101 = suspend. 110 = trickle, fast, or safety charge timer expired. 111 = battery detection.

Table 28. CHARGER_STATUS2, Register Address 0x09 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:5]	THR_STATUS[2:0]	R	Not applicable	THR pin status. 000 = off. 001 = battery cold. 010 = battery cool. 011 = battery warm. 100 = battery hot. 111 = thermistor is in normal operating temperature, between the battery cool and battery warm settings.
4	IPK_STAT	R	Not applicable	Peak current limit status bit. Set high if four or more peak inductor current limits are reached in succession.
3	Not used	R		Not used.
[2:0]	BATTERY_STATUS[2:0]	R	Not applicable	Battery status bus. 000 = battery monitor off. 001 = no battery. 010 = $V_{BSNS} < V_{TRK}$. 011 = $V_{TRK} \leq V_{BSNS} < V_{WEAK}$. 100 = $V_{BSNS} \geq V_{WEAK}$.

Table 29. CHARGER_FAULT, Register Address 0x0A Bit Descriptions[1]

Bit No.	Mnemonic	Access	Default	Description
[7:4]	Not used	R		Not used.
3	BAT_SHR	R/W	0	When this bit is high, a battery short circuit is detected.
2	IND_PEAK	R/W	0	When this bit is high, an inductor peak current-limit fault has occurred.
1	TSD_130	R/W	0	When this bit is high, the overtemperature early warning has occurred.
0	TSD_140	R/W	0	When this bit is high, the overtemperature condition is detected. The device shuts down due to an overtemperature condition.

[1] To reset the fault bits in the CHARGER_FAULT register, cycle the power on VBUSx, or read and then write the corresponding I^2C bit high continuously.

Table 30. BATTERY_SHORT, Register Address 0x0B Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:5]	TBAT_SHR[2:0]	R/W	100	Battery short timeout timer: 000 = 1 sec 001 = 2 sec 010 = 4 sec 011 = 10 sec 100 = 30 sec 101 = 60 sec 110 = 120 sec 111 = 180 sec

Bit No.	Mnemonic	Access	Default	Description
[4:3]	Not used	R		Not used.
[2:0]	VBAT_SHR[2:0]	R/W	100	Battery short voltage threshold level: 000 = 2.0 V 001 = 2.1 V 010 = 2.2 V 011 = 2.3 V 100 = 2.4 V 101 = 2.5 V 110 = 2.6 V 111 = 2.7 V

Table 31. BATTERY_THERMISTOR_CONTROL, Register Address 0x0C Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	ILIM_JEITA_COOL	R/W	0	Selects the battery charging current when in the cool temperature range of 0°C and 10°C (see Table 14). 0 = approximately 50% of programmed charge current. 1 = approximately 10% of programmed charge current.
6	TBAT_LOW	R/W	0	Selects the battery temperature low threshold. When the battery temperature is lower than TBAT_LOW, charging stops. 0 = 0°C. 1 = 10°C.
5	TBAT_HIGH	R/W	1	Selects the battery temperature high threshold. When the battery temperature is higher than TBAT_HIGH, charging stops. 0 = 45°C. 1 = 60°C.
4	R_NTC	R/W	Factory setting	Selects the battery thermistor NTC resistance. 0 = 10 kΩ at 25°C. 1 = 100 kΩ or 47 kΩ at 25°C.
[3:0]	BETA_NTC[1]	R/W	Factory setting	4-bit programming bus for NTC beta setting. 0000 = 2350. 0001 = 2600. 0010 = 2750. 0011 = 3000. 0100 = 3150. 0101 = 3350. 0110 = 3500. 0111 = 3600. 1000 = 3800. 1001 = 4000. 1010 = 4200. 1011 = 4400. 1100 = 4600. 1101 = 4800. 1110 = 5000. 1111 = 5200.

[1] The BETA_NTC bits are trimmed by factory setting; writing these bits in the application is not recommended.

Table 32. V_SOC_0, Register Address 0x0D Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_0	R/W	0x7C	The battery voltage when SOC is 0%. The default voltage is 3.5 V. Battery voltage (V) = (2.5 + V_SOC_0 × 0.008).

Table 33. V_SOC_5, Register Address 0x0E Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_5	R/W	0x91	The battery voltage when SOC is 5%. The default voltage is 3.66 V. Battery voltage (V) = (2.5 + V_SOC_5 × 0.008).

Table 34. V_SOC_11, Register Address 0x0F Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_11	R/W	0x94	The battery voltage when SOC is 11%. The default voltage is 3.684 V. Battery voltage (V) = (2.5 + V_SOC_11 × 0.008).

Table 35. V_SOC_19, Register Address 0x10 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_19	R/W	0x99	The battery voltage when SOC is 19%. The default voltage is 3.724 V. Battery voltage (V) = (2.5 + V_SOC_19 × 0.008).

Table 36. V_SOC_28, Register Address 0x11 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_28	R/W	0x9E	The battery voltage when SOC is 28%. The default voltage is 3.764 V. Battery voltage (V) = (2.5 + V_SOC_28 × 0.008).

Table 37. V_SOC_41, Register Address 0x12 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_41	R/W	0xA3	The battery voltage when SOC is 41%. The default voltage is 3.804 V. Battery voltage (V) = (2.5 + V_SOC_41 × 0.008)

Table 38. V_SOC_55, Register Address 0x13 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_55	R/W	0xAB	The battery voltage when SOC is 55%. The default voltage is 3.868 V. Battery voltage (V) = (2.5 + V_SOC_55 × 0.008).

Table 39. V_SOC_69, Register Address 0x14 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_69	R/W	0xB5	The battery voltage when SOC is 69%. The default voltage is 3.948 V. Battery voltage (V) = (2.5 + V_SOC_69 × 0.008).

Table 40. V_SOC_84, Register Address 0x15 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_84	R/W	0xC4	The battery voltage when SOC is 84%. The default voltage is 4.068 V. Battery voltage (V) = (2.5 + V_SOC_84 × 0.008)

Table 41. V_SOC_100, Register Address 0x16 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	V_SOC_100	R/W	0xD5	The battery voltage when SOC is 100%. The default voltage is 4.204 V. Battery voltage (V) = (2.5 + V_SOC_100 × 0.008).

Table 42. FILTER_SETTING1, Register Address 0x17 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	Not used	R		Not used.
[6:4]	FILTER_CHARGE	R/W	100	The filter limit (in C rate) of SOC in battery charging mode. The C rate is the battery charge or discharge current rate over the battery capacity. 000 = 0.125 C. 001 = 0.25 C. 010 = 0.5 C. 011 = 0.75 C. 100 = 1 C. 101 = 1.5 C. 110 = 2 C. 111 = 3 C.
3	Not used	R		Not used.
[2:0]	FILTER_DISCHARGE	R/W	010	The filter limit (in C rate) of SOC in battery discharging mode. The C rate is the battery charge or discharge current rate over the battery capacity. 000 = 0.125 C. 001 = 0.25 C. 010 = 0.5 C. 011 = 0.75 C. 100 = 1 C. 101 = 1.5 C. 110 = 2 C. 111 = 3 C

Table 43. FILTER_SETTING2, Register Address 0x18 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:2]	Not used	R/W	000000	Not used.
[1:0]	FILTER_IDLE	R/W	00	The filter limit of SOC during battery idle mode. 00 = FILTER_CHARGE/8. 01 = FILTER_CHARGE/16. 10 = FILTER_CHARGE/32. 11 = FILTER_CHARGE/64.

Table 44. RBAT_0, Register Address 0x19 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	RBAT_0	R/W	0x3F	The battery internal resistance at 0°C. The resistance range is 0 mΩ to 8160 mΩ and the default resistance is 2016 mΩ. Resistance value = RBAT_0 × 32 mΩ.

Table 45. RBAT_10, Register Address 0x1A Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	RBAT_10	R/W	0x3F	The battery internal resistance at 10°C. The resistance range is 0 mΩ to 8160 mΩ and the default resistance is 2016 mΩ. Resistance value = RBAT_10 × 32 mΩ.

Table 46. RBAT_20, Register Address 0x1B Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	RBAT_20	R/W	0x3F	The battery internal resistance at 20°C. The resistance range is 0 mΩ to 8160 mΩ and the default resistance is 2016 mΩ. Resistance value = RBAT_20 × 32 mΩ.

Table 47. RBAT_30, Register Address 0x1C Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	RBAT_30	R/W	0x3F	The battery internal resistance at 30°C. The resistance range is 0 mΩ to 8160 mΩ and the default resistance is 2016 mΩ. Resistance value = RBAT_30 × 32 mΩ.

Table 48. RBAT_40, Register Address 0x1D Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	RBAT_40	R/W	0x3F	The battery internal resistance at 40°C. The resistance range is 0 mΩ to 8160 mΩ and the default resistance is 2016 mΩ. Resistance value = RBAT_40 × 32 mΩ.

Table 49. RBAT_60, Register Address 0x1E Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	RBAT_60	R/W	0x3F	The battery internal resistance at 60°C. The resistance range is 0 mΩ to 8160 mΩ and the default resistance is 2016 mΩ. Resistance value = RBAT_60 × 32 mΩ.

Table 50. K_RBAT_CHARGE, Register Address 0x1F Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:6]	Not used	R		Not used.
[5:4]	K_RBAT_SOC	R/W	00	Battery internal resistance coefficient less than 20% capacity. 00 = RBAT at 0% SOC = R_{BAT} at 20% SOC. 01 = R_{BAT} at 0% SOC = 2 × R_{BAT} at 20% SOC. 10 = R_{BAT} at 0% SOC = 4 × R_{BAT} at 20% SOC. 11 = R_{BAT} at 0% SOC = 8 × R_{BAT} at 20% SOC.
[3:0]	K_RBAT_CHARGE	R/W	1000	Battery internal resistance coefficient for charging. The coefficient = 0.75 + K_RBAT_CHARGE/32.

Table 51. BAT_TEMP, Register Address 0x20 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	Not used	R		Not used.
6	BAT_TEMP_SOURCE	R/W	0	Battery temperature source selection bit. 0: from THR input. 1: from I^2C.
[5:0]	BAT_TEMP	R/W	11011	Battery temperature from I^2C. The program battery temperature range is between −2°C and +61°C. Temperature value (°C) = (BAT_TEMP − 2).

Table 52. BAT_SOC, Register Address 0x21 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	Not used	R		Not used.
[6:0]	BAT_SOC	R	Not applicable	Battery state of charge. SOC = BAT_SOC %, only valued between 0% and 100%.

Table 53. VBAT_READ_H, Register Address 0x22 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	VBAT_READ[12:5]	R	Not applicable	The battery voltage reading, highest eight bits, unit is mV. V_{BAT} (mV) = (VBAT_READ_H × 32 + VBAT_READ_L/8).

Table 54. VBAT_READ_L, Register Address 0x23 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:3]	VBAT_READ[4:0]	R	Not applicable	The battery voltage reading, lowest 5 bits, unit is mV. V_{BAT} (mV) = (VBAT_READ_H × 32 + VBAT_READ_L/8).
[2:0]	Not used	R		Not used.

Table 55. FUEL_GAUGE_MODE, Register Address 0x24 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:2]	Not used	R		Not used.
2	SLEEP_UPDATE_TIME	R/W	0	Select SOC update time in sleep mode. 0: 5 min. 1: 20 min.
1	FUEL_GAUGE_MODE	R/W	0	Fuel gauge operation mode. 1: enable sleep mode. 0: disable sleep mode.
0	FUEL_GAUGE_ENABLE	R/W	0	0: disable fuel gauge. 1: enable fuel gauge.

Table 56. SOC_RESET, Register Address 0x25 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	SOC reset	W	0	Write 1 to reset the BAT_SOC, VBAT_READ_H, and VBAT_READ_L registers.
[6:0]	Not used	R		Not used.

Table 57. BST_LED_CTRL, Register Address 0x26 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:6]	Not used	R		Not used.
5	EN_BST	R/W	0	Boost enable signal (only effective when the boost regulator is in standalone operation mode). 0 = disable boost output. 1 = enable boost output.
4	EN_LED5	R/W	0	Enable signal for LED5 individual sink (not effective if LED5 is configured as the grouped backlight). 0 = disable individual LED5 current sink. 1 = enable individual LED5 current sink.
3	EN_LED4	R/W	0	Enable signal for LED4 individual sink (not effective if LED4 is configured as the grouped backlight). 0 = disable individual LED4 current sink. 1 = enable individual LED4 current sink.
2	EN_LED3	R/W	0	Enable signal for LED3 individual sink (not effective if LED3 is configured as the grouped backlight). 0 = disable individual LED3 current sink. 1 = enable individual LED3 current sink.
1	EN_LED2	R/W	0	Enable signal for LED2 individual sink (not effective if LED2 is configured as the grouped backlight). 0 = disable individual LED2 current sink. 1 = enable individual LED2 current sink.

Bit No.	Mnemonic	Access	Default	Description
0	EN_BL	R/W	0	The grouped backlight enable signal. 0 = disable the grouped backlight. 1 = enable the grouped backlight.

Table 58. BST_CFG, Register Address 0x27 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	BST_MODE	R/W	0	This bit sets the boost regulator operation mode. 0 = LED operation mode. 1 = boost standalone operation mode.
6	BST_BL	R/W	0	This bit configures the boost regulator to provide the bias voltage to all active LED channels or only to the active LED backlight channels. (effective only when the boost regulator is configured in LED operation mode). 0 = set the boost regulator to provide the bias voltage for all active LED channels. In this configuration, the boost regulator provides the adaptive headroom regulation according to all active LED current sources. 1 = set the boost regulator to provide the bias voltage only to the active LED backlight channels.
5	FOVR	R/W	0	This bit configures the override feature in the backlight fade in and fade out. 0 = the fade in and fade out override is disabled. 1 = the fade in and fade out override is enabled.
4	Not used	R		Not used.
[3:2]	BST_OVP	R/W	00	This bit sets the overvoltage threshold in the boost output voltage in VOUT4 pin. 00 = 18.5 V. 01 = 15 V. 10 = 10 V. 11 = 5.6 V.
1	Not used	R		Not used.
0	BST_IPK	R/W	0	This bit sets the peak current limit for boost regulator. 0 = 600 mA peak current limit. 1 = 300 mA peak current limit.

Table 59. IBL_SET, Register Address 0x28 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:6]	Not used	R		Not used.
[5:0]	IBL[5:0]	R/W	000000	These bits set the LED current setting for the grouped backlight (LED1). All grouped backlight LED channels follow this current setting. A square law algorithm for 64 levels is used. 000000 = 0 mA. 000001 = 0.005 mA. 000010 = 0.020 mA. … 111101 = 18.750 mA. 111110 = 19.370 mA. 111111 = 20 mA.

Table 60. ILED2_SET, Register Address 0x29 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	BL_LED2	R/W	0	This bit sets LED2 as the grouped backlight or individual current sink. 0 = set as individual current sink. 1 = set as grouped backlight.
6	Not used	R		Not used.
[5:0]	ILED2[5:0]	R/W	000000	These bits set the individual LED current setting for LED2. This setting is not effective if LED2 is configured as the grouped LED backlight. A square law algorithm for 64 levels is used. 000000 = 0 mA. 000001 = 0.005 mA. 000010 = 0.020 mA. … 111101 = 18.750 mA. 111110 = 19.370 mA. 111111 = 20 mA.

Table 61. ILED3_SET, Register Address 0x2A Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	BL_LED3	R/W	0	This bit sets LED3 as the grouped backlight or individual current sink. 0 = set as individual current sink. 1 = set as grouped backlight.
6	Not used	R		Not used.
[5:0]	ILED3[5:0]	R/W	000000	Those bits set the individual LED current setting for LED3. This setting is not effective if LED3 is configured as the grouped LED backlight. A square law algorithm for 64 levels is used. 000000 = 0 mA. 000001 = 0.005 mA. 000010 = 0.020 mA. … 111101 = 18.750 mA. 111110 = 19.370 mA. 111111 = 20 mA.

Table 62. ILED4_SET, Register Address 0x2B Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	BL_LED4	R/W	0	This bit sets LED4 as the grouped backlight or individual current sink. 0 = set as individual current sink. 1 = set as grouped backlight.
6	Not used	R		Not used.
[5:0]	ILED4[5:0]	R/W	000000	Those bits set the individual LED current setting for LED4. This setting is not effective if LED4 is configured as the grouped LED backlight. A square law algorithm for 64 levels is used. 000000 = 0 mA. 000001 = 0.005 mA. 000010 = 0.020 mA. … 111101 = 18.750 mA. 111110 = 19.370 mA. 111111 = 20 mA.

Table 63. ILED5_SET, Register Address 0x2C Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	BL_LED5	R/W	0	This bit sets LED5 as the grouped backlight or individual current sink. 0 = set as individual current sink. 1 = set as grouped backlight.
6	Not used	R		Not used.
[5:0]	ILED5[5:0]	R/W	000000	Those bits set the individual LED current setting for LED5. This setting is not effective if LED5 is configured as the grouped LED backlight. A square law algorithm for 64 levels is used. 000000 = 0 mA. 000001 = 0.005 mA. 000010 = 0.020 mA. … 111101 = 18.750 mA. 111110 = 19.370 mA. 111111 = 20 mA.

Table 64. BL_FR, Register Address 0x2D Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	BL_FO[3:0]	R/W	0000	These bits set the fade out timer for the grouped LED backlight. The timer setting applies to the specific time starting from the maximum LED current code fade out to zero. Therefore, the real fade out time is shorter if the maximum LED current code is not being used.
				0000 = fade-out disabled. 0001 = 0.3 sec. 0010 = 0.6 sec. … 1101 = 3.9 sec. 1110 = 4.2 sec. 1111 = 4.5 sec.
[3:0]	BL_FI[3:0]	R/W	0000	These bits set the fade in timer for the grouped LED backlight. The timer setting applies to the specific time starting from zero fading into the maximum LED current code. Therefore, the real fade in time is shorter if the maximum LED current code is not being used. 0000 = fade in disabled. 0001 = 0.3 sec. 0010 = 0.6 sec. … 1101 = 3.9 sec. 1110 = 4.2 sec. 1111 = 4.5 sec.

Table 65. LED3_BLINK, Register Address 0x2E Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	LED3_OFF[3:0]	R/W	0000	These bits set the off timer for the LED3 blinking feature (not effective if this LED channel is configured as the grouped LED backlight). 0000 = the blinking feature is disabled. 0001 = 0.250 sec. 0010 = 0.500 sec. 0011 = 0.750 sec. … 1110 = 3.500 sec. 1111 = 3.750 sec.

Bit No.	Mnemonic	Access	Default	Description
[3:0]	LED3_ON[3:0]	R/W	0000	These bits set the on timer for the LED3 blinking feature (not effective if this LED channel is configured as the grouped LED backlight). 0000 = 0.125 sec. 0000 = 0.250 sec. 0010 = 0.375 sec. … 1110 = 1.875 sec. 1111 = 2.000 sec.

Table 66. LED4_Blink, Register Address 0x2F Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	LED4_OFF[3:0]	R/W	0000	These bits set the off timer for the LED4 blinking feature (not effective if this LED channel is configured as the grouped LED backlight). 0000 = the blinking feature is disabled. 0001 = 0.250 sec. 0010 = 0.500 sec. 0011 = 0.750 sec. … 1110 = 3.500 sec. 1111 = 3.750 sec
[3:0]	LED4_ON[3:0]	R/W	0000	These bits set the on timer for the LED4 blinking feature (not effective if this LED channel is configured as the grouped LED backlight). 0000 = 0.125 sec. 0000 = 0.250 sec. 0010 = 0.375 sec. … 1110 = 1.875 sec. 1111 = 2.000 sec.

Table 67. LED5_Blink, Register Address 0x30 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	LED5_OFF[3:0]	R/W	0000	These bits set the off timer for the LED4 blinking feature (not effective if this LED channel is configured as the grouped LED backlight). 0000 = the blinking feature is disabled. 0001 = 0.250 sec. 0010 = 0.500 sec. 0011 = 0.750 sec. … 1110 = 3.500 sec. 1111 = 3.750 sec.
[3:0]	LED5_ON[3:0]	R/W	0000	These bits set the on timer for the LED5 blinking feature (not effective if this LED channel is configured as the grouped LED backlight). 0000 = 0.125 sec. 0000 = 0.250 sec. 0010 = 0.375 sec. … 1110 = 1.875 sec. 1111 = 2.000 sec.

Table 68. LED_STATUS, Register Address 0x31 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:5]	Not used	R		Not used.
4	LED5_OPEN[1]	R	Not applicable	This bit records the LED5 status 0: LED5 channel is not open 1: LED5 channel is open
3	LED4_OPEN[1]	R	Not applicable	This bit records the LED4 status 0: LED4 channel is not open 1: LED4 channel is open
2	LED3_OPEN[1]	R	Not applicable	This bit records the LED3 status 0: LED3 channel is not open 1: LED3 channel is open
1	LED2_OPEN[1]	R	Not applicable	This bit records the LED2 status 0: LED2 channel is not open 1: LED2 channel is open
0	LED1_OPEN[1]	R	Not applicable	This bit records the LED1 status 0: LED1 channel is not open 1: LED1 channel is open

[1] To reset any bit in this register, power cycle VBUSx or write the corresponding I²C bit high.

Table 69. LDO_CTRL, Register Address 0x32 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:3]	Not used	R		Not used.
2	EN_LDO3	R/W	Factory setting	Enable signal for LDO3 (or Load Switch 3) 0 = disable LDO3 (or Load Switch 3) 1 = enable LDO3 (or Load Switch 3)
1	EN_LDO2	R/W	Factory setting	Enable signal for LDO2 (or Load Switch 2) 0 = disable LDO2 (or Load Switch 2) 1 = enable LDO2 (or Load Switch 2)
0	EN_LDO1	R/W	1	Enable signal for LDO1 (or Load Switch 1) 0 = disable LDO1 (or Load Switch 1) 1 = enable LDO1 (or Load Switch 1)

Table 70. LDO_CFG, Register Address 0x33 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	Not used	R		Not used.
6	DSCG_LDO3	R/W	0	This bit configures the output discharge functionality for LDO3 or Load Switch 3 0 = discharge functionality disabled 1 = discharge functionality enabled
5	DSCG_LDO2	R/W	0	This bit configures the output discharge functionality for LDO2 or Load Switch 2 0 = discharge functionality disabled 1 = discharge functionality enabled
4	DSCG_LDO1	R/W	0	This bit configures the output discharge functionality for LDO1 or Load Switch 1 0 = discharge functionality disabled 1 = discharge functionality enabled
3	Not used	R		Not used.
2	MODE_LDO3	R/W	0	This bit sets LDO3 as an LDO or load switch 0 = LDO mode 1 = load switch mode
1	MODE_LDO2	R/W	0	This bit sets LDO2 as an LDO or load switch 0 = LDO mode 1 = load switch mode

Bit No.	Mnemonic	Access	Default	Description
0	MODE_LDO1	R/W	0	This bit sets LDO1 as an LDO or load switch 0 = LDO mode 1 = load switch mode

Table 71. VID_LDO12, Register Address 0x34 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	VID_LDO2	R/W	Factory setting	These bits set the output voltage in LDO2. These bits have no effect when this channel is set as a load switch. 0000 = 4.20 V. 0001 = 3.60 V. 0010 = 3.30 V. 0011 = 3.15 V. 0100 = 3.00 V. 0101 = 2.85 V. 0110 = 2.50 V. 0111 = 2.30 V. 1000 = 2.10 V. 1001 = 1.80 V. 1010 = 1.50 V. 1011 = 1.40 V. 1100 = 1.30 V. 1101 = 1.20 V. 1110 = 1.10 V. 1111 = 1.00 V.
[3:0]	VID_LDO1	R/W	Factory setting	These bits set the output voltage in LDO1. These bits have no effect when this channel is set as a load switch. 0000 = 4.20 V. 0001 = 3.60 V. 0010 = 3.30 V. 0011 = 3.15 V. 0100 = 3.00 V. 0101 = 2.85 V. 0110 = 2.50 V. 0111 = 2.30 V. 1000 = 2.10 V. 1001 = 1.80 V. 1010 = 1.50 V. 1011 = 1.40 V. 1100 = 1.30 V. 1101 = 1.20 V. 1110 = 1.10 V. 1111 = 1.00 V.

Table 72. VID_LDO3, Register Address 0x35 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	Not used	R		Not used.
[3:0]	VID_LDO3	R/W	Factory setting	These bits set the output voltage in LDO3. These bits have no effect when this channel is set as a load switch. 0000 = 4.20 V. 0001 = 3.60 V. 0010 = 3.30 V. 0011 = 3.15 V. 0100 = 3.00 V. 0101 = 2.85 V. 0110 = 2.50 V. 0111 = 2.30 V. 1000 = 2.10 V. 1001 = 1.80 V. 1010 = 1.50 V. 1011 = 1.40 V. 1100 = 1.30 V. 1101 = 1.20 V. 1110 = 1.10 V. 1111 = 1.00 V.

Table 73. PGOOD_STATUS, Register Address 0x36 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	Not used	R		Not used.
3	VBUSOK	R	Not applicable	This bit shows real-time status of VBUSx voltage. 0 = the voltage at the VBUSx pin is below V_{VBUSOK} or above V_{VBUS_OV}. 1 = the voltage at the VBUSx pin is above V_{VBUSOK} and below V_{VBUS_OV}.
2	BATOK	R	Not applicable	This bit shows the real-time status of the battery voltage. 0 = battery voltage is lower than V_{WEAK}. 1 = battery voltage is higher than V_{WEAK}.
1	PG4_BST	R	Not applicable	This bit shows the real-time power-good status for the boost regulator. This bit is effective only in boost standalone fixed output mode. 0 = boost regulator power-good status is low. 1 = boost regulator power-good status is high.
0	PG1_LDO1	R	Not applicable	This bit shows the real-time power good status for LDO1. This bit is not effective if the LDO regulator is configured as a load switch mode. 0 = LDO1 power-good status is low. 1 = LDO1 power-good status is high.

Table 74. PGOOD_MASK, Register Address 0x37 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:4]	Not used	R		Not used.
3	VBUSOK_MASK	R/W	Factory setting	This bit configures the external PGOOD pin. 0 = do not output the V_{VBUSx} voltage status signal to the external PGOOD pin. 1 = output V_{BUS} voltage status signal to the external PGOOD pin.
2	BATOK_MASK	R/W	0	This bit configures the external PGOOD pin. 0 = do not output BATOK signal to the external PGOOD pin. 1 = output the BATOK signal to the external PGOOD pin.

Bit No.	Mnemonic	Access	Default	Description
1	PG4_BST_MASK	R/W	0	This bit configures the external PGOOD pin. This bit is only effective in boost standalone fixed output mode. 0 = do not output the boost PGOOD signal to the external PGOOD pin. 1 = output the boost PGOOD signal to the external PGOOD pin.
0	PG1_LDO1_MASK[1]	R/W	Factory setting	This bit configures the external PGOOD pin. This bit is not effective if the LDO regulator is configured as a load switch mode. 0 = do not output the LDO1 PGOOD signal to the external PGOOD pin. 1 = output the LDO1 PGOOD signal to the external PGOOD pin.

[1] When the PGOOD pin is selected for PG1_LDO1_MASK, the ADP5350 quiescent current increases to 4 µA typically.

Table 75. CHARGER_INTERRUPT_ENABLE, Register Address 0x38 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	EN_IND_PEAK_INT	R/W	0	When high, the inductor peak current-limit interrupt is enabled.
6	EN_THERM_LIM_INT	R/W	0	When high, the isothermal charging interrupt is allowed.
5	EN_WD_INT	R/W	0	When high, the watchdog alarm interrupt is allowed.
4	EN_TSD_INT	R/W	0	When high, the overtemperature 130°C warning interrupt is allowed.
3	EN_THR_INT	R/W	0	When high, the THR temperature thresholds interrupt is allowed.
2	EN_BAT_INT	R/W	0	When high, the battery voltage thresholds interrupt is allowed.
1	EN_CHG_INT	R/W	0	When high, the charger mode change interrupt is allowed.
0	EN_VIN_INT	R/W	0	When high, the VBUSx pin voltage thresholds interrupt is allowed.

Table 76. CHARGER_INTERRUPT_FLAG, Register Address 0x39 Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
7	IND_PEAK_INT[1]	R	0	When high, this bit indicates an interrupt caused by an inductor peak current limit.
6	THERM_LIM_INT[1]	R	0	When high, this bit indicates an interrupt caused by isothermal charging.
5	WD_INT[1]	R	0	When high, this bit indicates an interrupt caused by the watchdog alarm. The watchdog timer expires within 2 sec or 4 sec depending on the t_{WD} setting of 32 sec or 64 sec, respectively.
4	TSD_INT[1]	R	0	When high, this bit indicates an interrupt caused by an overtemperature fault.
3	THR_INT[1]	R	0	When high, this bit indicates an interrupt caused by THR temperature thresholds.
2	BAT_INT[1]	R	0	When high, this bit indicates an interrupt caused by battery voltage thresholds.
1	CHG_INT[1]	R	0	When high, this bit indicates an interrupt caused by a charger mode change.
0	VIN_INT[1]	R	0	When high, this bit indicates an interrupt caused by VBUSx voltage thresholds.

[1] These bits reset to 0 automatically when read.

Table 77. BOOST_LDO_INTERRUPT_ENABLE, Register Address 0x3A Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:3]	Not used	R		Not used.
2	EN_LED_OPEN_INT	R/W	0	0 = LED open events does not trigger the interrupt pin. 1 = LED open events triggers the interrupt pin.
1	EN_PG4_BST_INT	R/W	0	0 = power-good warning on the boost regulator does not trigger the interrupt pin. 1 = power-good warning on the boost regulator triggers the interrupt pin.
0	EN_PG1_LDO1_INT	R/W	0	0 = power-good warning on LDO1 does not trigger the interrupt pin. 1 = power-good warning on LDO1 triggers the interrupt pin.

Table 78. BOOST_LDO_INTERRUPT_FLAG, Register Address 0x3B Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:3]	Not used	R		Not used.
2	LED_OPEN_INT[1]	R	0	When high, this bit indicates an interrupt caused by LED open-circuit faults.
1	PG4_BST_INT[1]	R	0	When high, this bit indicates an interrupt caused by a power-good warning on the boost regulator.
0	PG1_LDO1_INT[1]	R	0	When high, this bit indicates an interrupt caused by a power-good warning on LDO1.

[1] These bits reset to 0 automatically when read.

Table 79. DEFAULT_SET, Register Address 0x3C Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:0]	DEFAULT_SET	W	0	Write 0x7F to this bit to reset all register to default values.

Table 80. NTC47K_SET, Register Address 0x3D Bit Descriptions

Bit No.	Mnemonic	Access	Default	Description
[7:1]	Not used	R		Not used.
0	NTC_47K	R/W	1	Select battery thermistor NTC resistance, effective when R_NTC = 1. 0 = 100 kΩ at 25°C. 1 = 47 kΩ at 25°C.

APPLICATIONS INFORMATION

EXTERNAL COMPONENTS

Buck Inductor Selection

The high switching frequency of the ADP5350 buck converter allows the selection of small chip inductors. Suggested buck inductors are shown in Table 81.

The peak-to-peak inductor current ripple, I_{RIPPLE}, is calculated using the following equation:

$$I_{RIPPLE} = \frac{V_{ISOS} \times (V_{ISOS} - V_{CFL1})}{V_{ISOS} \times f_{SW} \times L1}$$

where:
V_{ISOS} is the ISOS node output voltage.
V_{CFL1} is the converter input voltage at the CFL1 node.
f_{SW} is the switching frequency.
$L1$ is the buck output inductor value.

The minimum dc current rating of the inductor must be greater than the inductor peak current. The inductor peak current, I_{PEAK}, is calculated using the following equation:

$$I_{PEAK} = I_{CHG} + I_{LOAD_MAX} + \frac{I_{RIPPLE}}{2}$$

Inductor conduction losses are caused by the flow of current through the inductor, which has an associated internal dc resistance (DCR). Larger inductors have smaller DCR values, which may decrease inductor conduction losses. Inductor core losses are related to the magnetic permeability of the core material. Because the buck regulators are high switching frequency dc-to-dc converters, shielded ferrite core material is recommended for its low core losses and low electromagnetic interference (EMI).

Boost Inductor Selection

The inductor is an essential part of the boost switching regulator. It stores energy during the on time, and transfers that energy to the output through the output rectifier during the off time. Use inductance in the range of 2 µH to 10 µH. In general, lower inductance values have higher saturation current and lower series resistance for a given physical size. However, lower inductance results in higher peak current that can lead to reduced efficiency and greater input and/or output ripple and noise. Peak-to-peak inductor ripple current at close to 30% of the maximum dc input current typically yields an optimal compromise. Suggested boost inductors are shown in Table 82.

The input V_{IN4} and output V_{OUT4} voltages determine the switch duty cycle, which in turn determine the inductor ripple current. Calculate the inductor ripple current in a steady state using the following equation:

$$I_{RIPPLE4} = \frac{V_{IN4} \times (V_{OUT4} - V_{IN4})}{V_{OUT4} \times f_{SW4} \times L2}$$

Make sure that the peak inductor current, the maximum input current plus half the inductor ripple current is below the rated saturation current of the inductor. Likewise, make sure that the maximum rated rms current of the inductor is greater than the maximum dc input current to the regulator.

VBUSx Capacitor Selection

According to the USB 2.0 specification, USB peripherals have a detectable change in capacitance on VBUSx when VBUSx are attached. The peripheral device VBUSx bypass capacitance must be at least 1 µF but not larger than 10 µF. The combined capacitance for the VBUSx and CFL1 pins must not exceed 10 µF at any temperature or dc bias condition. Suggested VBUSx capacitors are shown in Table 83.

CFL1 Capacitor Selection

The CFL1 pin serves the ADP5350 as the buck dc-to-dc regulator input capacitor. The rms current rating of the input capacitor current must be larger than the value calculated by the following equation:

$$I_{C_RMS} = (I_{CHG} + I_{LOAD_MAX}) \sqrt{\frac{V_{ISOS} \times (V_{CFL1} - V_{ISOS})}{V_{CFL1}}}$$

To minimize supply noise, place the input capacitor as close as possible to the CFL1 pin of the charger. As with the output capacitor, a low ESR capacitor is recommended.

The effective capacitance needed for stability, which includes temperature and dc bias effects, is a minimum of 2 µF and a maximum of 7 µF. A list of suggested capacitors is shown in Table 84.

Table 81. Suggested Buck Inductors

Vendor	Part Number	L (µH)	Typical DC Current (A)	Maximum DCR (mΩ)	Size
Wurth	74479976215	1.5	1.2	125	0806
TDK	VLS201612CX-1R5M	1.5	1.9	89	0806

Table 82. Suggested Boost Inductors

Vendor	Part Number	L (µH)	Typical DC Current (A)	Maximum DCR (mΩ)	Size
Wurth	74479776247A	4.7	0.9	140	0806
TDK	VLS201612CX-4R7M	4.7	1.12	252	0806

CFL2 Capacitor Selection

The CFL2 pin is the internal regulator output that provides the power supply for post stage control circuits, including the fuel gauge, boost LED, and LDOs. To ensure stable performance of the internal regulator, the recommended components for the CFL2 capacitor are given in Table 85.

ISOS and ISOB Capacitor Selection

Higher output capacitor values reduce the output voltage ripple and improve load transient response. When choosing this value, it is also important to account for the loss of capacitance due to output voltage dc bias.

To guarantee the performance of the charger in various operation modes, including trickle charge, CC charge, and CV charge, it is imperative that the effects of dc bias, temperature, and tolerances on the behavior of the capacitors be evaluated for each application.

The peak-to-peak output voltage ripple for the selected output capacitor and inductor values is calculated using the following equation:

$$V_{RIPPLE} = \frac{I_{RIPPLE}}{8 \times f_{SW} \times C_{OUT}}$$

Capacitors with lower effective series resistance (ESR) are preferable to guarantee low output voltage ripple, as shown in the following equation:

$$ESR_{COUT} \leq \frac{V_{RIPPLE}}{I_{RIPPLE}}$$

Table 83. Suggested VBUSx Capacitors

Vendor	Part Number	Value (µF)	Voltage (V)	Size
Murata	GRM188R61E225K	2.2	25	0603
TDK	C1608X5R1E225	2.2	25	0603

Table 84. Suggested CFL1 Capacitors

Vendor	Part Number	Value (µF)	Voltage (V)	Size
Murata	GRM188R60J475K	4.7	6.3	0603
TDK	C1608X5R0J475K	4.7	6.3	0603

Table 85. Suggested CFL2 Capacitors

Vendor	Part Number	Value (µF)	Voltage (V)	Size
Murata	GRM188R60J225K	2.2	6.3	0603
TDK	C1608X5R0J475K	2.2	6.3	0603

Table 86. Suggested ISOS and ISOB Capacitors

Vendor	Part Number	Value (µF)	Voltage (V)	Size
Murata	GRM188R60J106K	10	6.3	0603
TDK	C1608X5R0J106M080AB	10	6.3	0603

LDO Capacitor Selection

Connecting a 1 µF capacitor from VIN123 to AGND reduces the circuit sensitivity to the PCB layout, especially when long input traces or high source impedance are encountered.

The ADP5350 is designed for operation with small, space-saving ceramic capacitors, but functions with most commonly used capacitors as long as care is taken with regard to the ESR value. The ESR of the output capacitor affects the stability of the LDO control loop. A minimum of 1 µF capacitance with an ESR of 1 Ω or less is recommended to ensure stability of the ADP5350. Transient response to changes in load current is also affected by output capacitance. Using a larger value of output capacitance improves the transient response of the ADP5350 to large changes in load current.

Table 87. Suggested LDO Capacitors

Vendor	Part Number	Value (µF)	Voltage (V)	Size
Murata	GRM155R60J105KE19D	1	6.3	0402
TDK	CGB2A3X5R0J105M033BB	1	6.3	0402

Boost Capacitor Selection

The ADP5350 requires input and output decoupling capacitors to supply transient currents while maintaining a constant input and output voltage. Use a low ESR input capacitor, 4.7 µF or greater, to prevent noise at the VIN4 node. Place the capacitor between the VIN4 pin and PGND4 as close to the ADP5350 as possible. Ceramic capacitors are preferred because of their low ESR characteristics.

The output capacitor maintains the output voltage and supplies current to the load while the boost switch is on. The value and characteristics of the output capacitor greatly affect the output voltage ripple and stability of the regulator. Use a low ESR output capacitor; ceramic dielectric capacitors are preferred.

For very low ESR capacitors, such as ceramic capacitors, the ripple current due to the capacitance is calculated as follows. Because the capacitor discharges during the on time the charge removed from the capacitor is the load current multiplied by the on time. Choose the output capacitor based on the following equation:

$$C_{OUT4} \geq \frac{I_{L2} \times (V_{OUT4} - V_{IN4})}{f_{SW4} \times V_{OUT4} \times V_{RIPPLE4}}$$

where:
I_{L2} is the average inductor current.
$V_{RIPPLE4}$ is boost output voltage ripple.

Table 88. Suggested Boost Capacitors

Vendor	Part Number	Value (µF)	Voltage (V)	Size
Murata	GRM188R61C475ME11	4.7	25	0603
TDK	C1608X5R1E475M080AC	4.7	25	0603
Murata	GRM188R61E106MA73	10	25	0603
TDK	C1608X5R1E106M080AC	10	25	0603

PCB LAYOUT GUIDELINES

Poor layout can affect ADP5350 performance, causing EMI and electromagnetic compatibility (EMC) problems, ground bounce, and voltage losses. Poor layout can also affect regulation and stability. A good layout is implemented using the following guidelines:

- Place the decoupling capacitor, inductor, input capacitor, and output capacitor close to the IC.
- Use a ground plane with several vias connecting to the component side ground to further reduce noise interference on sensitive circuit nodes.
- Use a dedicated trace to connect the BSNS pin to the battery pack output node for accurate sensing of the battery voltage.
- Use Size 0603 or Size 0402 resistors and capacitors to achieve the smallest possible footprint solution on boards where space is limited.

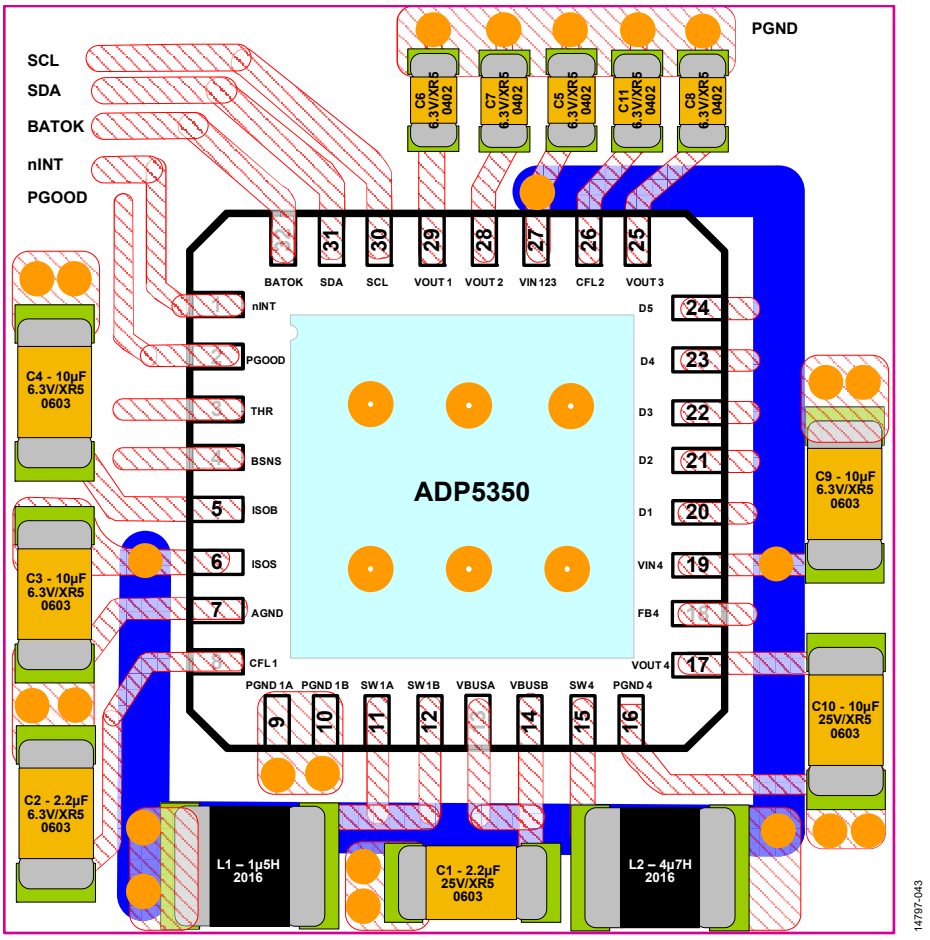


Figure 59. Recommended Layout

TYPICAL APPLICATION CIRCUITS

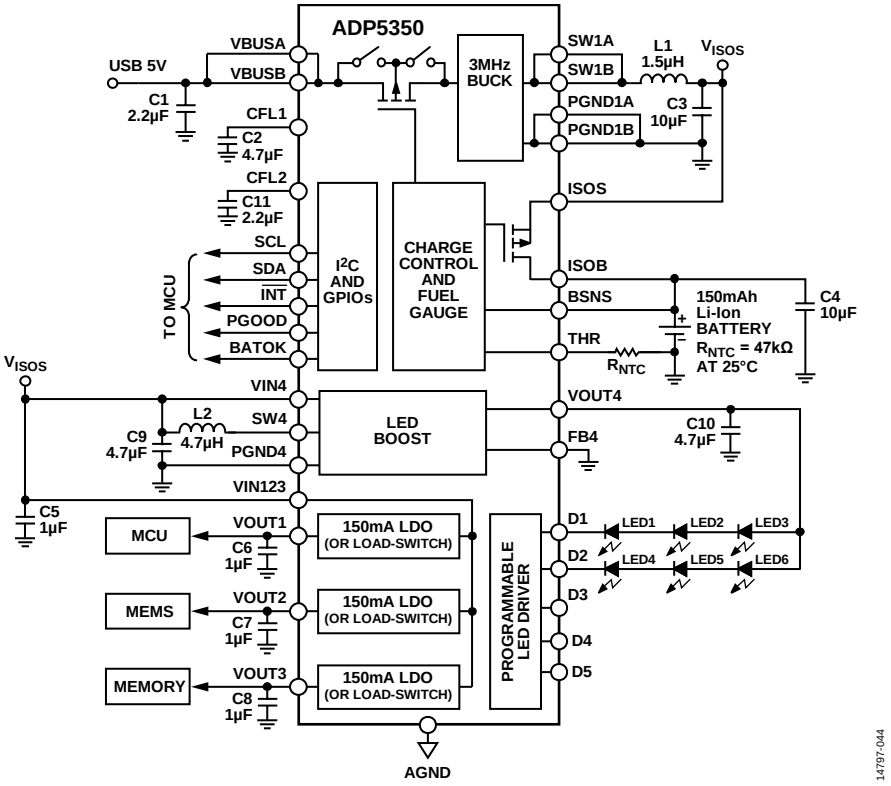


Figure 60. Li-Ion Battery Charger Application with LED Panel

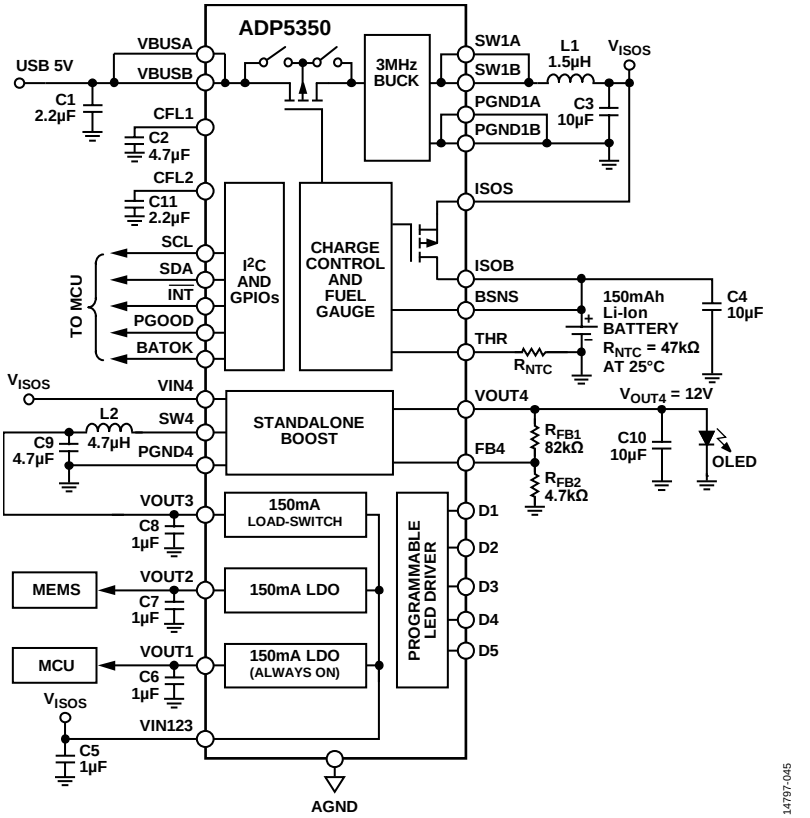


Figure 61. True Shutdown Standalone Boost for OLED Panel Application

FACTORY-PROGRAMMABLE OPTIONS

Table 89. Fuse-Programmable Trim Options for the ADP5350

Parameter	Value	Default Setting
I²C Address	0x44 0x45 0x64 0x65	0x44
R_NTC	10 kΩ 100 kΩ/47 kΩ	100 kΩ/47 kΩ
BETA_NTC	2350 2600 2750 3000 3150 3350 3500 3600 3800 4000 4200 4400 4600 4800 5000 5200	3800
EN_CHG	Charger is enabled Charger is disabled	Charger is disabled
EN_LDO2	LDO2 is enabled LDO2 is disabled	LDO2 is disabled
EN_LDO3	LDO3 is enabled LDO3 is disabled	LDO3 is disabled
VID_LDO1, VID_LDO2, VID_LDO3	4.20 V 3.60 V 3.30 V 3.15 V 3.00 V 2.85 V 2.50 V 2.30 V 2.10 V 1.80 V 1.50 V 1.40 V 1.30 V 1.20 V 1.10 V 1.00 V	3.3 V
VBUSOK_MASK	Do not output the V_{VBUSx} voltage status signal to the external PGOOD pin Output the V_{VBUSx} voltage status signal to external PGOOD pin	Output the V_{VBUSx} voltage status signal to the external PGOOD pin
PG1_LDO1_MASK	Do not output the LDO1 PGOOD signal to the external PGOOD pin Output the LDO1 PGOOD signal to external PGOOD pin	Do not output the LDO1 PGOOD signal to the external PGOOD pin

OUTLINE DIMENSIONS

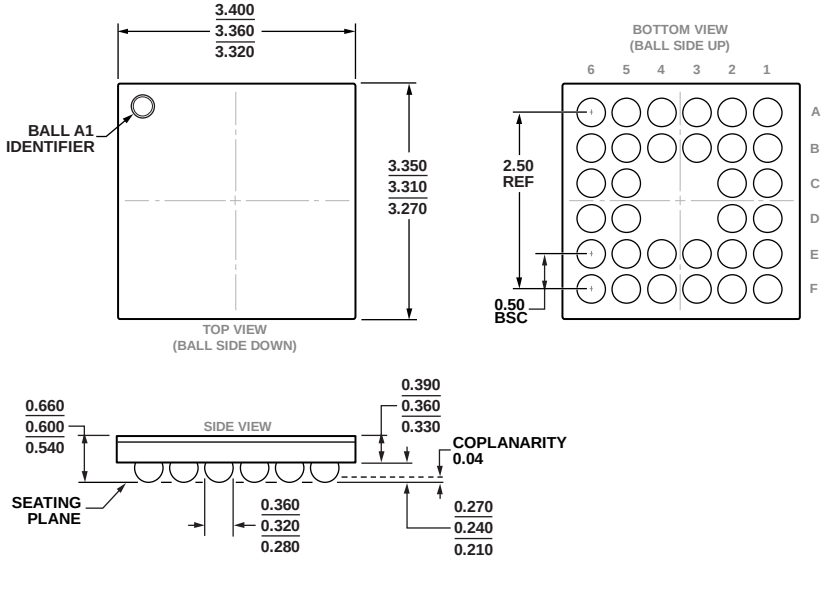
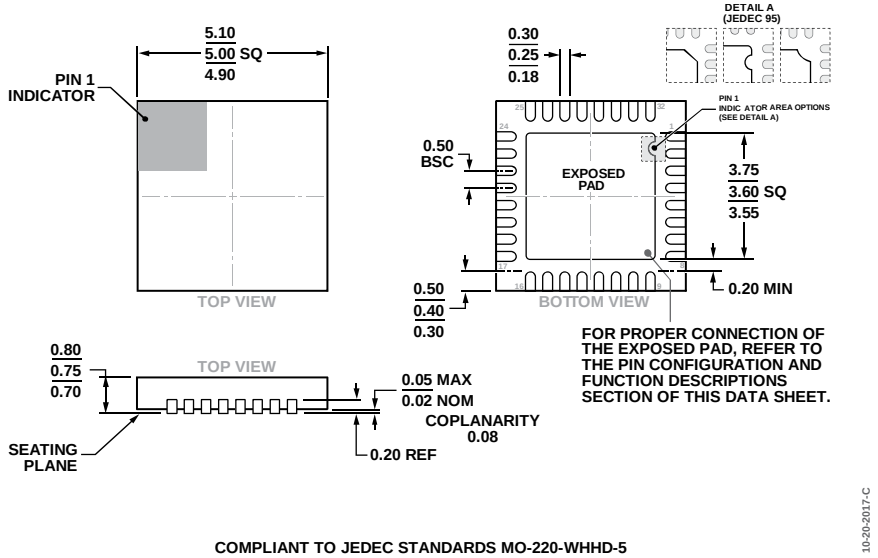


Figure 62. 32-Ball Wafer Level Chip Scale Package [WLCSP]
(CB-32-1)
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-220-WHHD-5

Figure 63. 32-Lead Lead Frame Chip Scale Package [LFCSP]
5 mm × 5 mm Body and 0.75 mm Package Height
(CP-32-12)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option
ADP5350ACBZ-1-R7	−40°C to +125°C	32-Ball Wafer Level Chip Scale Package [WLCSP]	CB-32-1
ADP5350ACPZ-1-R7	−40°C to +125°C	32-Lead Lead Frame Chip Scale Package [LFCSP]	CP-32-12
ADP5350CB-EVALZ		Evaluation Board	
ADP5350CP-EVALZ		Evaluation Board	

[1] Z = RoHS Compliant Part.

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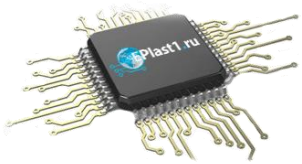

Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)
Факс: 8 (812) 320-02-42
Электронная почта: org@eplast1.ru
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.